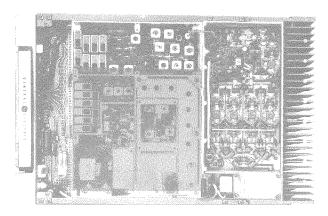
(Supersedes LBI4600)

MASTR II MAINTENANCE MANUAL

25-50 MHz, 100-WATT TRANSMITTER



SPECIFICATIONS *

Frequency Range

Power Output

Crystal Multiplication Factor

Frequency Stability
5C-ICOM with EC-ICOM
5C-ICOM or EC-ICOM
2C-ICOMS

Spurious and Harmonic Emission

Modulation

Modulation Sensitivity

Audio Frequency Characteristics

Distortion

Deviation Symmetry

Duty Cycle

Maximum Frequency Spread: (2 to 8 channels)

25-30 MHz 30-36 MHz 36-42 MHz 42-50 MHz 25-50 MHz

100 Watts (Adjustable from 50 to 100 Watts at 30 to 50 MHz, and from 75 to 100 Watts at 25 to 30 MHz)

3

±0.0005% (-40°C to +70°C) ±0.0002% (0°C to +55°C) ±0.0002% (-40°C to +70°C)

At least 85 dB below full rated power output

Adjustable from 0 to ± 5 kHz swing with instantaneous modulation limiting.

80 to 120 Millivolts

Within +1 dB to -3 dB of a 6-dB/octave preemphasis from 300 to 3000 Hz per EIA standards. Post limiter filter per FCC and EIA.

Less than 2% (1000 Hz) Less than 3% (300 to 3000 Hz)

0.5 kHz maximum

EIA 20% Intermittent

Full Specifications 1 dB Degradation

.160 MHz .320 MHz .200 MHz .400 MHz .240 MHz .470 MHz .280 MHz .540 MHz

^{*}These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.

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--- WARNING ---

Although the highest DC voltage in MASTR II Mobile Equipment is supplied by the vehicle battery, high currents may be drawn under short circuit conditions. These currents can possibly heat metal objects such as tools, rings, watchbands, etc., enough to cause burns. Be careful when working near energized circuits!

DESCRIPTION

MASTR II transmitters are crystal-controlled phase modulated and designed for one-through eight-frequency operation in the 25 to 50 megahertz band. The solid state transmitter utilizes both integrated circuits (ICs) and discrete components, and consists of the following assemblies:

- Exciter Board; with audio, modulator, amplifier and multiplier stages.
- Power Amplifier Assembly; with amplifier, driver, PA, power control, filter and antenna switch.

CIRCUIT ANALYSIS

EXCITER

The exciter uses nine transistors and two integrated circuits to drive the PA assembly. The exciter can be equipped with up to eight Integrated Circuit Oscillator Modules (ICOMs). The ICOM crystal frequency ranges from approximately 8.33 to 16.67 megahertz, and the crystal frequency is multiplied three times (divided by four

and multiplied by 12 for a multiplication factor of three).

Audio, supply voltages and control functions are connected from the system board to the exciter board through P902.

Centralized metering jack J103 is provided for use with GE Test Set Model 4EX3All or Test Kit 4EX8K12. The test set meters the modulator, multiplier and amplifier stages.

ICOMS

Three different types of ICOMs are available for use in the exciter. Each of the ICOMs contains a crystal-controlled Colpitts oscillator, and two of the ICOMs contain compensator ICs. The different ICOMs are:

- 5C-ICOM contains an oscillator and a 5 part-per-million (±0.0005%) compensator IC. Provides compensation for EC-ICOMs.
- EC-ICOM contains an oscillator only. Requires external compensation from a 5C-ICOM.
- 2C-ICOM contains an oscillator and a
 2 PPM (±0.0002%) compensator IC. Will not provide compensation for an EC-ICOM.

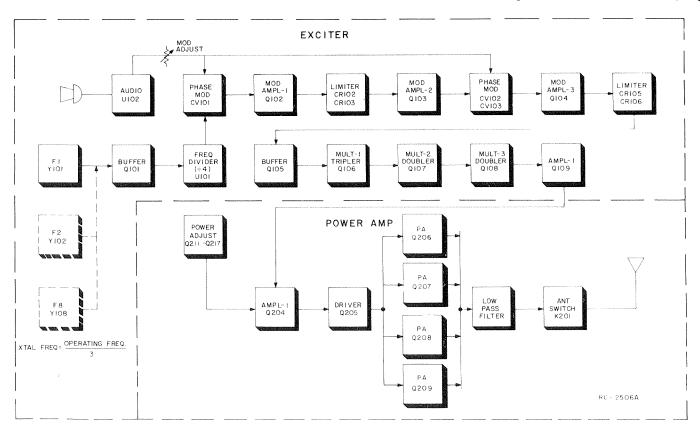


Figure 1 - Transmitter Block Diagram

The ICOMs are enclosed in an RF shielded can with the type ICOM (5C-ICOM, EC-ICOM or 2C-ICOM) printed on the top of the can.
Access to the oscillator trimmer is obtained through a hole on the top of the can.

Frequency selection is accomplished by switching the ICOM keying lead (terminal 6) to A- by means of the frequency selector switch on the control unit. In single-frequency radios, a jumper from H9 to H10 in the control unit connects terminal 6 of the ICOM to A-. The oscillator is turned on by applying a keyed +10 Volts to the external oscillator load resistor. RF bypassing is provided for all unused keying loads in eight frequency radios. In two frequency radios the six unused keying leads are shorted to ground.

--- CAUTION ---

All ICOMs are individually compensated at the factory and cannot be repaired in the field. Any attempt to repair or change an ICOM frequency will void the warranty.

In standard 5 PPM radios using EC-ICOMs, at least one 5C-ICOM must be used. The 5C-ICOM is normally used in the receiver F1 position, but can be used in any transmit or receive position. One 5C-ICOM can provide compensation for up to 15 EC-ICOMs in the transmit and receiver. Should the 5C-ICOM compensator fail in the open mode, the EC-ICOMs will still maintain 2 PPM frequency stability from 0°C to 55°C (+32°F to 131°F) due to the regulated compensation voltage (5 Volts) from the 10-Volt regulator IC. If desired, up to 16 5C-ICOMs may be used in the radio.

The 2C-ICOMs are self-compensated at 2 PPM and will not provide compensation for EC-ICOMs $_{\circ}$

Oscillator Circuit

The quartz crystals used in ICOMs exhibit the traditional "S" curve characteristics of output frequency versus operating temperature.

At both the coldest and hottest temperatures, the frequency increases with increasing temperature. In the middle temperature range (approximately 0°C to +55°C), frequency decreases with increasing temperature.

Since the rate of change is nearly linear over the mid-temperature range, the output frequency change can be compensated by choosing a parallel compensation capacitor with a temperature coefficient approximately equal and opposite that of the crystal.

Figure 2 shows the typical performance of an uncompensated crystal as well as the typical performance of a crystal which has been matched with a properly chosen compensation capacitor.

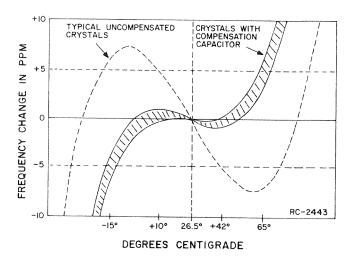


Figure 2 - Typical Crystal Characteristics

At temperatures above and below the mid-range, additional compensation must be introduced. An externally generated compensation voltage is applied to a varactor (voltage-variable capacitor) which is in parallel with the crystal.

A constant bias of 5 Volts (provided from Regulator IC U901 in parallel with the compensator) establishes the varactor capacity at a constant value over the entire midtemperature range. With no additional compensation, all of the oscillators will provide 2 PPM frequency stability from 0°C to 55°C (+32°F to 131°F).

Compensator Circuits

Both the 5C-ICOMs and 2C-ICOMs are temperature compensated at both ends of the temperature range to provide instant frequency compensation. An equivalent ICOM circuit is shown in Figure 3.

The cold end compensation circuit does not operate at temperatures above 0°C. When the temperature drops below 0°C, the circuit is activated. As the temperature decreases, the equivalent resistance decreases and the compensation voltage increases.

The increase in compensation voltage decreases the capacity of the varactor in the oscillator, increasing the output frequency of the ICOM.

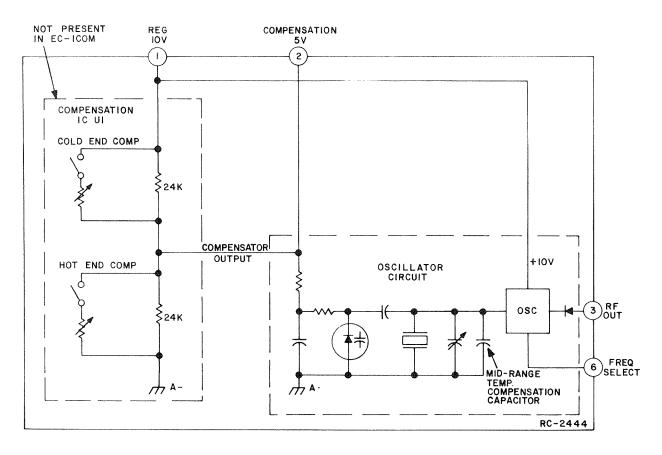


Figure 3 - Equivalent ICOM Circuit

The hot end compensation circuit does not operate at temperatures below +55°C. When the temperature rises above +55°C, the circuit is activated. As the temperature increases, the equivalent resistance decreases and the compensation voltage decreases. The decrease in compensation voltage increases the capacity of the varactor, decreasing the output frequency of the ICOM.

SERVICE NOTE: Proper ICOM operation is dependent on the closely-controlled input voltages from the 10-Volt regulator. Should all of the ICOMs shift off frequency, check the 10-Volt regulator module.

AUDIO IC

The transmitter audio circuitry is contained in audio IC UlO2. A simplified drawing of the audio IC is shown in Figure 4.

Audio from the microphone at pin 12 is coupled through pre-emphasis capacitor C1 to the base of Q1 in the operational amplifier-limiter circuit. Collector voltage for the transistorized microphone preamplifier is supplied from pin 11 through microphone collector load resistor R18 to pin 12.

The operational amplifier-limiter circuit consists of Q1, Q2 and Q3. Q3 provides limiting at high signal levels. The gain of the operational amplifier circuit is fixed by negative feedback through R19, R20 and the resistance in the network (pin 9).

The output of Q3 is coupled through a de-emphasis network (R10 and C3) to an active post-limiter filter consisting of C4, C5, C6, R11, R12, R13, R15, R17, and Q4.

Following the post-limiter filter is class A amplifier Q5. The output of Q5 is coupled through MOD ADJUST potentiometer R127 to the phase modulators.

 $\frac{\text{SERVICE NOTE}}{\text{Audio IC are}}: \quad \text{If the DC voltages to the} \\ \text{and no audio output can} \\ \text{be obtained, replace Ulo2.}$

For radios equipped with Channel Guard, tone from the encoder is applied to the phase modulators through CHANNEL GUARD MOD ADJUST potentiometer R128, and resistors R110, R121 and R124. Instructions for setting R128 are contained in the modulation adjustment section of the Transmitter Alignment Procedure.

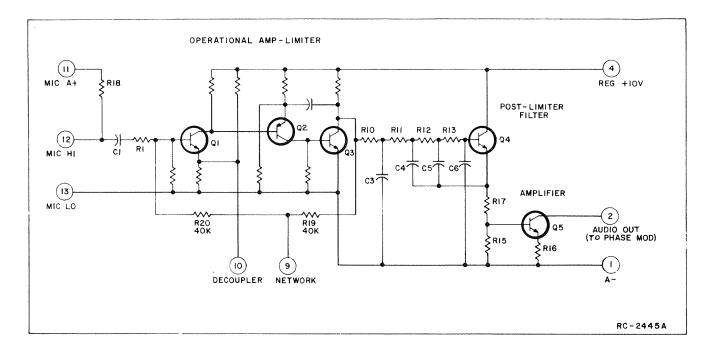


Figure 4 - Simplified Audio IC

FREQUENCY DIVIDER IC

The output at pin 3 of the selected ICOM is coupled through buffer amplifier Q101 to frequency divider U101, which divides the oscillator frequency by 4. The divider consists of two J-K flip-flops connected as a binary counter.

When the transmitter is not keyed (no ICOMs on), Q101 is saturated (turned on) with its collector voltage near zero. Keying the transmitter starts one of the ICOMs, and its output cuts Q101 on and off once each cycle. As Q101 turns off during each cycle, the drop in collector voltage causes the left flip-flop to change state. Assume the flip-flop was in the "0" state (the output at "Q" near A-). The first cycle of the oscillator output causes it to switch to the "1" stage (output at "Q" approximately 5 Volts). The second cycle will cause the flip-flop to switch back to the "0" state. Therefore, it requires two oscillator cycles to switch the left flip-flop through one complete cycle from "0" to "1" and back to "0".

When the left flip-flop switches from "1" to "0", it causes the right flip-flop to change state. It requires two cycles of the left flip-flop to switch the right flip-flop from "0" to "1" and back to "0". Therefore, four cycles of the oscillator output are required for each cycle of output from pin 9 of UlO1.

If U101 was operating into a pure resistive load, its output would be a square wave. However, the modulator circuit presents a tuned load to the IC, so that harmonics are filtered out and the waveform at the junction of C102 and C103 (modulator input) is essentially a sine wave at one-fourth the oscillator frequency. The output of the frequency divider is coupled through DC blocking capacitor C102 to the first modulator stage.

PHASE MODULATORS, AMPLIFIER & MULTIPLIERS

The first phase modulator is varactor (voltage-variable capacitor) CV101 in series with tunable coil L101. This network appears as a series-resonant circuit to the RF output of the oscillator. An audio signal applied to the modulator circuit through blocking capacitor C115 varies the bias of CV101, resulting in a phase modulated output. A voltage divider network (R108 and R109) provides the proper bias for varactors CV101, CV102 and CV103.

The output of the first modulator is coupled through blocking capacitor Cl06 to the base of Class A amplifier Ql02. The first modulator stage is metered through a metering network consisting of Rl15, Rl50, Cl07 and CR101. Diodes CR102 and CR103 remove any amplitude modulation in the modulator output.

Following Q102 is another Class A Amplifier, Q103. The output of Q103 is applied to the second modulator stage. The second modulator consists of two cascaded modulator circuits consisting of CV102, L102, L103 and CV103. Following the second modulator is a Class A amplifier Q104. The output of the second modulator stage is metered through R133, R145, C117 and CR104, and is applied to the base of buffer Q105. Diodes CR105 and CR106 remove any amplitude modulation in the second modulator output.

Buffer Q105 is saturated when no RF signal is present. Applying an RF signal to Q105 provides a sawtooth waveform at its collector to drive the class C tripler, Q106. The tripler stage is metered through R146. The output of Q106 is coupled through tuned circuits T101, T102 and T103 to the base of doubler Q107. T101, T102 and T103 are tuned to one-fourth of the operating frequency. The doubler stage is metered through R147.

The output of Q107 is coupled through tuned circuits T104 and T105 to the base of second doubler Q108. T104 and T105 are tuned to one-half the operating frequency. Q108 is metered through R148.

The output of Q108 is coupled through three tuned circuits (T106, T107 and T108) to the base of amplifier Q109. The circuits are tuned to the transmitter operating frequency.

Q109 is a class C amplifier with a collector feed network consisting of C139, C141, L104, L108 and R143. The stage is metered through R149. The amplifier collector circuit consists of C142, C143, C146 and L105, and matches the amplifier output to the input of the power amplifier assembly.

POWER AMPLIFIER

The PA assembly uses six RF power transistors and seven transistors in the Power Control circuitry to provide a power output of 100 Watts. The broadband PA has no adjustments other than Power Control potentiometer R261.

Supply voltage for the PA is connected through power leads from the system board to feedthrough capacitors C297 and C298 on the bottom of the PA assembly. C297, C298 and C299, L297 and L298 prevent RF from getting on the Power leads. Diode CR295 will cause the main fuse in the fuse assembly to blow if the polarity of the power leads is reversed.

Centralized metering jack J205 is provided for use with GE Test Set Model 4EX3A11 or Test Kit 4EX8K12. The Test Set meters the Ampl-1 drive (exciter output), Ampl-1 power control, Driver and PA current. L251 through L257 in conjunction with bypass capacitors C4210 through C4216 keep RF off of the metering leads.

RF AMPLIFIERS

The exciter output is coupled through an RF cable to PA input jack J201. RF from the exciter is coupled through DC blocking capacitor C201 to the base of Class C amplifier Q204 through a matching network. The network matches 50-ohm input to the base of Q204, and consists of C205, C206, C207, L201 and L202. R203 and R204 lower the gain of the amplifier stage.

Part of the RF input is rectified by CR201 and used to activate the Power Control circuit. Another portion of the rectified RF is applied to voltage dividers R201 and R202 for metering the Ampl-1 drive at J205.

Collector voltage to Q204 (Ampl-1) is controlled by the Power Control Circuit, and is applied through a collector stabilizing network consisting of L258 and R272 and collector feed network L205 and C213. The collector voltage of Q204 is metered through R271 at J205.

Following Q204 is a matching network (C208 through C212, L204 and L206) to a resistive pad (R207, R208 and R209). The output of the resistor network is applied to the base of the Class C driver (Q205) through a matching network consisting of C218, C219, C220, L207 and L208. Resistors R207 through R215 lower the gain of driver Q205.

Collector voltage to Q205 is coupled through a collector stabilizing network consisting of L259 and R273 and collector feed network L211 and C226. Collector current for Q205 is metered across tapped manganin resistor R249 at J205 (DRIVER CURRENT). The reading is taken on the one-Volt scale with the High Sensitivity button pressed, and read as 10 amperes full scale.

Following Q205 is a matching network (C221 through C225, L210 and L214) that matches the driver output to the input of the first power divider circuit (C230, C231, L214, L215 and L216).

The power amplifier stages consist of four identical paralleled Class C amplifiers (Q206 through Q209). The output of the first power divider circuit is applied to four additional power dividers. C234-L217 and C235-L218 provide drive for Q206 and Q207, while C236-L219 and C237-L220 provide drive for Q208 and Q209.

The output of C234-L217 is applied to the base of Q206 an impedance-matching network (L217, L221, C238, C242 and C243). Resistors R220 through R223, R236 and R237 hower the gain of Q206. Supply voltage for Q206 is coupled through a collector-stabilizing network consisting of L260 and R274 and collector feed network L223 and C270.

Collector current for Q206 through Q209 is metered across tapped maganin resistors R250 and R251 at J205 (PA CURRENT). The

reading is taken on the one-Volt scale with the High Sensitivity button pressed, and read as 30 amperes full scale.

The output of Q206 is coupled through a matching network (C250, C251, L229, C258, C259, C266 and L237), applied to a lumped-constant combiner circuit (C280, L237 and L241), and added to the output of Q207. The outputs of Q206 and Q207 are added to the outputs of Q208 and Q209 through lumped-constant power combiner circuit C284, L249, C294, L250 and C285. The combined PA output is applied to 50-ohm microstrip W205, and then to an M-derived, constant K low-pass filter. The filter output is applied to the antenna through antenna switch K201.

Capacitors C286 through C293, C217, C228 and C233 provide ground isolation for \pm ground operation.

---- WARNING -

The stud mounted RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic, or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

POWER CONTROL CIRCUIT

When the transmitter is keyed, rectified RF from CR201 is applied to the base of switch Q211, turning it on. Turning on Q211 turns on voltage regulator Q212 which supplies a constant voltage to Power Adjust potentiometer R261.

Q215, Q216 and Q217 operate as an amplifier chain to supply voltage to the collector of Q204 (Ampl-1). The setting of R261 determines the voltage applied to the base of Q215. The higher the voltage at the base of Q215, the harder the amplifiers conduct, supplying more collector voltage to Q204. The lower the voltage at the base of Q215, the less collector voltage is supplied to Q204. Reducing the supply voltage to Q204 reduces the drive to Q205, thereby reducing the power output of the PA. The power output can be adjusted by R261 from approximately 50 to 100 Watts (75 to 100 Watts at 25-30 MHz).

Temperature protection is provided by Q213, Q214, and thermistor RT201 which is mounted in the PA heatsink. Under normal operating conditions, the circuit is inactive (Q213 is on and Q214 is off). When the heatsink temperature reaches approximately 100°C, the resistance of RT201 decreases. This increases the base voltage applied to Q213, turning it off. Turning off Q213 allows Q214 to turn on, decreasing the voltage at Power Adjust potentiometer R261. This reduces the base voltage to Q215 which causes Q216 and Q217 to conduct

less, reducing the collector voltage to Q204 (Amp1-1). This reduces the transmitter output power, keeping the heatsink at a maximum of approximately 100°C. When the heatsink temperature decreases below 100°C, the temperature control circuit turns off, allowing the normal transmitter power output.

CARRIER CONTROL TIMER

The Carrier Control Timer option shuts off the transmitter on each transmission after a one-minute timing cycle, and alerts the operator that the transmitter is off by means of an alarm tone in the speaker. The transmitter can be turned on again by releasing and keying the push-to-talk switch on the microphone.

The timing cycle (transmitter keyed time) is normally set at the factory for a duration of one minute. A potentiometer permits the timing cycle to be adjusted from approximately 15 seconds to 3 minutes.

MAINTENANCE

DISASSEMBLY

To service the transmitter from the top:

 Pull the locking handle down, then pry up the top cover at the front notch and lift off the cover.

To service the transmitter from the bottom:

- 1. Pull the locking handle down and pull the radio out of the mounting frame.
- 2. Remove the top cover, then loosen the two bottom cover retaining screws and remove the bottom cover (see Figure 5).
- 3. To gain access to the bottom of the exciter board, remove the six screws

 (A) holding the exciter board and its bottom cover to the module mounting frame, and remove the bottom cover.

To remove the exciter board from the radio:

- 1. Unplug the exciter/PA cable (B)
- 2. Remove the six screws (A) holding the exciter board and its bottom cover to the module mounting frame (see Figure 6).
- 3. Press straight down on the plug-in exciter from the top to avoid bending the pins when unplugging the board from the system board jack.

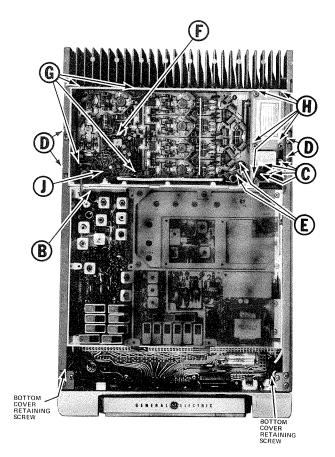


Figure 5 - Disassembly Procedure-Top View

To remove the PA assembly:

- Remove the PA top cover and unplug the exciter/PA cable (B), the antenna, receiver and PTT cables (C).
- 2. Remove the four side-rail screws D, and unsolder the power cables from the bottom of the PA assembly if desired.

To remove the PA board:

- 1. Remove the PA top cover and unplug the exciter/PA cable $\stackrel{\frown}{(B)}$.
- 2. Unsolder the two feedthrough coils $\stackrel{\textstyle (E)}{}$ and the thermistor leads $\stackrel{\textstyle (F)}{}$.
- 3. Remove the PA transistor hold-down nuts and spring washers on the bottom of the PA assembly.
- 4. Remove the four PA board mounting screws

 (G), the five screws in the filter casting (H), and the retaining screw in Q210 (J), and lift the board out.

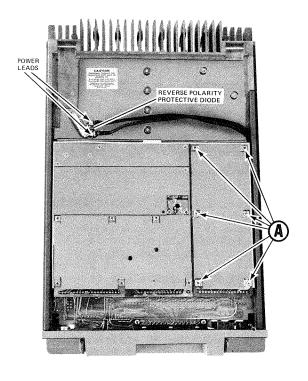


Figure 6 - Disassembly Procedure-Bottom View

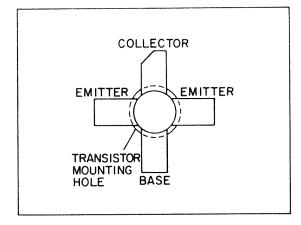
PA TRANSISTOR REPLACEMENT

--- WARNING -

The stud mounted RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

To replace the PA RF transistors:

- 1. Unsolder one lead at a time with a 50-Watt soldering iron. Use a scribe to hold the lead away from the printed circuit board until the solder cools.
- 2. Turn the transmitter over.
- 3. Hold the body of the transistor to prevent it from turning. Remove the transistor hold-down nut and spring washer through the hole in the heatsink with an 11/32-inch nut-driver. Lift out the transistor, and remove the old solder from the printed circuit board with a de-soldering tool such as a SOLDA PULLT®. Special care should be taken to prevent damage to the printed circuit board runs.



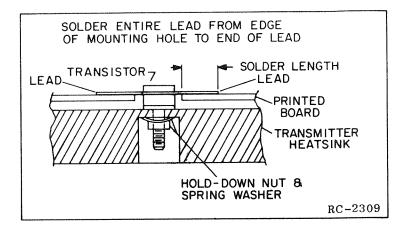


Figure 7 - Lead Identification

Figure 8 - Lead Forming

- 4. Trim the new transistor leads (if required) to the lead length of the removed transistor. Cut the collector lead at a 45° angle for future identification (see Figure 7). The letter "C" on the top of the transistor indicates the collector.
- 5. Apply a coating of silicon grease around the transistor mounting surface, and place the transistor in the mounting hole. Align the leads as shown in the Outline Diagram. Then hold the body of the transistor and replace the holding-down nut and spring-washer using moderate torque (8 inch-pounds). A torque wrench must be used for this adjustment since transistor damage can result if too little or too much torque is used.
- 6. Make sure that the transistor leads are formed as shown in Figure 8 so that the leads can be soldered to the printed circuit pattern, starting from the inner edge of the mounting hole.
- 7. Solder the leads to the printed circuit pattern. Start at the inner edge of mounting hole and solder the remaining length of transistor lead to the board. Use care not to use excessive heat that causes the printed wire board runs to lift up from the board. Check for shorts and solder bridges before applying power.

- CAUTION -

Failure to solder the transistor leads as directed may result in the generation of RF loops that could damage the transistor or may cause low power output.

GENERAL ELECTRIC COMPANY • MOBILE COMMUNICATIONS DIVISION WORLD HEADQUARTERS • LYNCHBURG, VIRGINIA 24502 U.S.A.



EQUIPMENT REQUIRED

- 1. GE Test Set Model 4EX3All or Test Kit 4EX8Kl2.
- 2. A 50-ohm wattmeter connected to antenna jack J906.
- 3. A frequency counter.

PRELIMINARY CHECKS AND ADJUSTMENTS

- 1. Place ICOMs on Exciter Board (crystal frequency = operating frequency ÷ 3).
- 2. For a large change in frequency or a badly mis-aligned transmitter, pre-set the slugs in T101 through T108, and L101, L102 and L103 to the bottom of the coil form.

NOTE

The tuning frequency for multi-frequency transmitters is determined by the operating frequency and the frequency spread between transmitters. Refer to the table below for maximum frequency spread.

TRANSMITTER ALIGNMENT

3. For multi-frequency transmitters with a frequency spread less than that specified in column (1), tune the transmitters to the lowest frequency.

For frequency spread exceeding the limits specified in column (1), tune the transmitters using a center frequency tune up ICOM. Except the maximum frequency spread can be extended to the limits specified in column (3) with 1 dB degradation.

For tuning L101, L102, L103. Always tune L101, L102, L103 on the lowest frequency.

Multi-frequency Transmitter Tuning

Transmitter Frequency Range	MAXIMUM FREQUENCY SPREAD						
	(1) without center tuning	with center tuning	with center tuning (1dB degradation)				
25 - 30 MHz	.080 MHz	.160 MHz	.320 MHz				
30 - 36 MHz	.100 MHz	.200 MHz	.400 MHz				
36 - 42 MHz	.120 MHz	.240 MHz	.470 MHz				
42 - 50 MHz	.140 MHz	.280 MHz	.540 MHz				

- 4. Connect the red plug on the GE Test Set to the System Board metering jack, and the black plug to the Exciter metering jack. Set the polarity to +, and set the range to the Test 1 position (1-Volt position for 4EX8K12) for all adjustments. NOTE: With the Test Set connected to the PA metering jack, the voltage reading at position "F" with the HIGH SENSITIVITY button pressed may be converted to driver collector current by reading the current as 10 amperes full scale. The voltage reading at position "G" with the HIGH SENSITIVITY button pressed may be converted to PA collector current by reading the current as 30 amperes full scale.
- 5. All adjustments are made with the transmitter keyed. Unkey the transmitter between steps to avoid unnecessary heating.

STEP	METER POSITION	TUNING CONTROL	METER READING	PROCEDURE
1.	MOD-1 PINZ	L101	Maximum	Tune L101 for maximum meter reading.
2.	в ри	L102 & L103	Maximum	Tune L102 and then L103 for the maximum meter reading.
3.	C MULT-1 P * N 3	T101 & T102	See Procedure	Tune 1.101 for maximum dip meter reading, and then tune T102 for maximum meter reading.
4.	D MULT-2 P*x) 1	T103, T102, T101 & T104	Tune T103 for maximum meter reading and re-adjust T102 and T101 for maximum meter reading. Then tune T104 for a dip in meter reading.	
5.	F MULT-3 PIN 7	T105, T104, T106 & T107	See Procedure	Tune T105 for maximum meter reading and re-adjust T104 for maximum meter reading. Then tune T106 for a dip in meter reading and T107 for maximum meter reading.
6.	G AMPL-1 PIN 6	T108, T107 & T106	See Procedure	Tune T108 for maximum meter reading, and then re-adjust T107 and T106 for maximum meter reading.
7.	D AMPL-1 DRIVE (on PA)	C143, C156	Maximum	Move the black metering plug to the Power Amplifier metering jack and tune C143 and C156 for maximum meter reading.
8.		R261		With the battery voltage at 13.4 Volts or the PA collector voltage at 12.4 Volts, set Power Adjust potentiometer R261 on the PA board for the desired power output (from 50 to 100 Watts at 30-50 MHz, or from 75 to 100 Watts at 25-30 MHz). If the battery voltage is not at 13.4 Volts or the collector voltage at 12.4 Volts and full rated output is desired (50 to 100 Watts at 30-50 MHz, or from 75 to 100 Watts at 25-30 MHz), set R261 for the output power according to the battery voltage or collector voltage shown in Figure 10. NOTE The PA collector voltage is measured as described in the PA POWER INPUT section.

SYSTEM BOARD METERING JACK

ANTENNA JACK J906

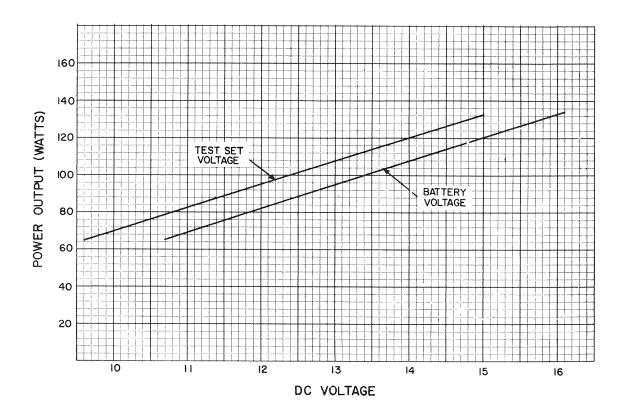


Figure 10 - Power Output Setting Chart

ALIGNMENT PROCEDURE

25-50 MHz, 100-WATT TRANSMITTER

M FREQUENCY ADJUSTMENT

requency to determine if any adjustment is required. The freth a frequency meter or counter with an absolute accuracy that than the tolerance to be maintained, and with the entire radio an ambient temperature of $26.5\,^{\circ}\mathrm{C}$ (79.8 $^{\circ}\mathrm{F})$.

uld be reset only when the frequency shows deviations in excess

en the radio is at 26.5°C (79.8°F).

y other temperature within the range of $-5\,^{\circ}\text{C}$ to $+55\,^{\circ}\text{C}$ 31 $^{\circ}\text{F}$).

ation limit (±2 PPM or ±5 PPM) at any temperature within f -40°C to -5°C (-40°F to +23°F) or +55°C to +70°C 158°F)

s required, pry up the cover on the top of the ICOM to expose $\ensuremath{\mathbf{e}}$ of the following procedures:

an ambient temperature of 26.5°C (79.8°F), set the oscillator \overline{ng} frequency.

t at an ambient temperature of 26.5°C, setting errors can be

ing error to ± 0.6 PPM (which is considered reasonable for 5 PPM

the radio at 26.5°C ($\pm 5\,^{\circ}\mathrm{C})$ and set the oscillator to frequency, or-

the radio at 26.5°C ($\pm 10\,^{\circ}\text{C})$ and offset the oscillator, as a of actual temperature, by the amount shown in Figure 9.

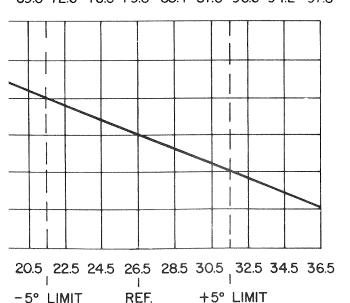
ing error to ± 0.35 PPM (which is considered reasonable for : Maintain unit at 26.5°C (± 5 °C) and offset the oscillator, n of actual temperature, by the amount shown in Figure 9.

e ambient temperature of the radio is 18.5°C (65.4°F). At urve shows a correction factor of 0.3 PPM. (At 25 MHz, 1 PPM PPM is 50 Hz).

frequency of 50 MHz, set the oscillator for a reading of 15 Hz an the licensed operating frequency. If a negative correction temperatures above 26.5°C), set the oscillator for the indie licensed operating frequency.

DEGREES FAHRENHEIT

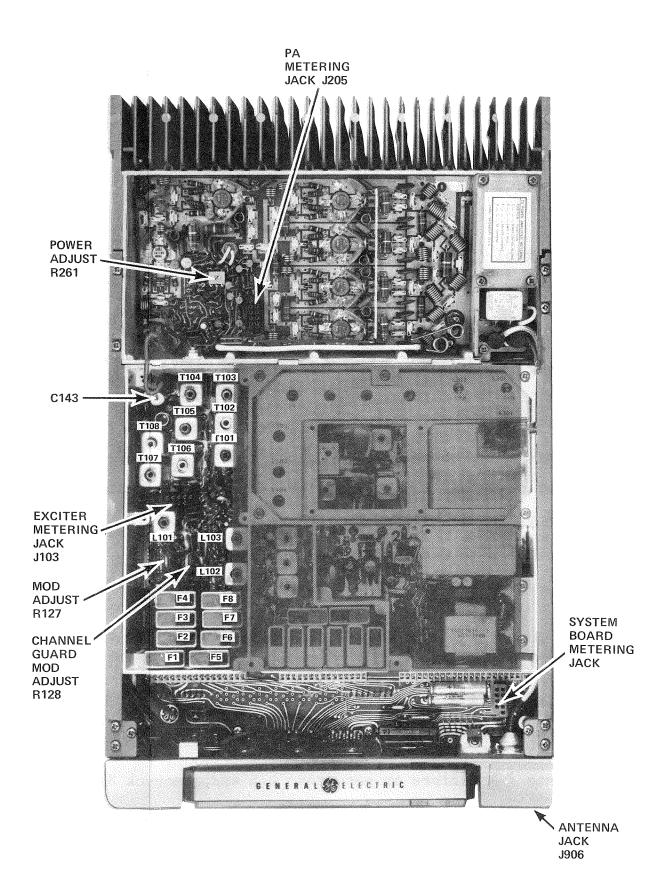
69.0 72.6 76.6 79.8 83.4 87.0 90.6 94.2 97.8



DEGREES CENTIGRADE

RC-2453

) - Frequency Characteristics Vs. Temperature



TRANSMITTER ALIGNMENT

EQUIPMENT REQUIRED

- 1. GE Test Set Model 4EX3All or Test Kit 4EX8Kl2.
- 2. A 50-ohm wattmeter connected to antenna jack J906.
- 3. A frequency counter.

PRELIMINARY CHECKS AND ADJUSTMENTS

1. Place ICOMs on Exciter Board (crystal frequency = operating frequency = 3).

For tuning L101, L102, L103. Always tune L101, L102, L103 on the lowest frequency.

For a large change in frequency or a badly mis-aligned transmitter, pre-set the slugs in T101 through T108, and L L103 to the bottom of the coil form.

The tuning frequency for multi-frequency transmitters is determined by the operating frequency and the frequeransmitters. Refer to the table below for maximum frequency spread.

3. For multi-frequency transmitters with a frequency spread less than that specified in column (1), tune the transmi quency.

For frequency spread exceeding the limits specified in column (1), tune the transmitters using a center frequency maximum frequency spread can be extended to the limits specified in column (3) with 1 dB degradation.

Multi-frequency Transmitter Tuning

Transmitter Frequency Range		MAXIMUM FREQUENCY SI	PREAD
	(1) without center tuning	with center tuning	with center
25 - 30 MHz	.080 MHz	.160 MHz	
30 - 36 MHz	.100 MHz	.200 MHz	Service Control of the Control of th
36 - 42 MHz	.120 MHz	.240 MHz	
42 - 50 MHz	.140 MHz	.280 MHz	

- 4. Connect the red plug on the GE Test Set to the System Board metering jack, and the black plug to the Exciter mete to +, and set the range to the Test 1 position (1-Volt position for 4EX8K12) for all adjustments, NOTE: With the PA metering jack, the voltage reading at position "F" with the HIGH SENSITIVITY button pressed may be converted to by reading the current as 10 amperes full scale. The voltage reading at position "G" with the HIGH SENSITIVITY be verted to PA collector current by reading the current as 30 amperes full scale.
- 5. All adjustments are made with the transmitter keyed. Unkey the transmitter between steps to avoid unnecessary he

STEP	METER POSITION	TUNING CONTROL	METER READING	PROCEDURE
SIEF	METER POSITION	TOWING CONTROL	MEIRA READING	PROCEDURE
1.	MOD-1 PENZ	L101	Maximum	Tune L101 for maximum meter reading.
2.	B pin)	L102 & L103	Maximum	Tune L102 and then L103 for the maximum
3.	C MULT-1 PaN 3	T101 & T102	See Procedure	Tune 101 for maximum dip meter reading, maximum meter reading.
4.	D MULT-2 P*N 1	T103, T102, T101 & T104	See Procedure	Tune T103 for maximum meter reading and for maximum meter reading. Then tune T1 reading.
5.	MULT-3 PIP 7	T105, T104, T106 & T107	See Procedure	Tune T105 for maximum meter reading and meter reading. Then tune T106 for a dip for maximum meter reading.
6.	G AMPL-1 PIN 6	T108, T107 & T106	See Procedure	Tune T108 for maximum meter reading, and T106 for maximum meter reading.
7.	D AMPL-1 DRIVE ON (on PA)	C143, C156	Maximum	Move the black metering plug to the Power and tune C143 and C156 for maximum meter
8.		R261		With the battery voltage at 13.4 Volts of at 12.4 Volts, set Power Adjust potention for the desired power output (from 50 to or from 75 to 100 Watts at 25-30 MHz).
				If the battery voltage is not at 13.4 Voltage at 12.4 Volts and full rated output Watts at 30-50 MHz, or from 75 to 100 Wat R261 for the output power according to the lector voltage shown in Figure 10.
				The PA collector voltage is measu the PA POWER INPUT section.
	1			

MODULATION LEVEL ADJUSTMENT

The MOD ADJUST (R127) was adjusted to the proper setting before shipment and should not normally require readjustment. This setting permits approximately 75% modulation for the average voice level. The audio peaks which would cause overmodulation are clipped by the modulation limiter. The limiter, in conjunction with the de-emphasis network, instantaneously limits the slope of the audio wave to the modulator, thereby preventing overmodulation while preserving intelligibility.

TEST EQUIPMENT

- 1. An audio oscillator (GE Model 4EX6Al0)
- 2. A frequency modulation monitor
- 3. An output meter or a VTVM
- 4. GE Test Set Models 4EX3All or 4EX8Kl2

PROCEDURE

- 1. Connect the audio oscillator and the meter across audio input terminals J10 (Green-Hi) and J11 (Black-Lo) on GE Test Set, or across P902-6 (Mike High) through a 0.5 microfarad (or larger) DC blocking capacitor, and P902-5 (Mike-Low) on the System Board.
- 2. Adjust the audio oscillator for 1-Volt RMS at 1000 Hz.
- For transmitters without Channel Guard, set MOD ADJUST R127 for a 4.5-kilohertz swing with the deviation polarity which gives the highest reading as indicated on the frequency modulation monitor.
- 4. For transmitters with Channel Guard, set Channel Guard MOD ADJUST R128 for zero tone deviation. Next, with the 1-Volt signal at 1000 Hz applied, set MOD ADJUST R127 for a 3.75 kHz deviation. Then remove the signal from the audio oscillator and set Channel Guard MOD ADJUST R128 for 0.75 kHz tone deviation.
- 5. For multi-frequency transmitters, set the deviation as described in Steps 3 or 4 on the channel producing the largest amount of deviation.

PA POWER INPUT

For FCC purposes, the PA power input can be determined by measuring the PA supply voltage and PA current, and using the following formula:

where:

P, is the power input in Watts,

PA voltage is measured with Test Set Model 4EX3All in Position G on the 15-Volt range (read as 15 Volts full scale), and with the polarity switch in the (-) position. With Test Set Model 4EX8K12, use the B+ position and the 1-Volt range (read as 15 Volts full scale), with the HIGH SENSITIVITY button pressed and the polarity switch in the (-) position.

PA current is measured with the Test Set in Position G in the Test 1 position, and with the HIGH SENSITIVITY button pressed (30 amperes full scale).

Example.

 $P_i = 12.4 \text{ Volts x 8.5 amperes} = 105.4 \text{ Watts}$

ICOM FREQUENCY ADJUSTMENT

First, check the frequency to determine if any adjustment is required. The frequency should be set with a frequency meter or counter with an absolute accuracy that is 5 to 10 times better than the tolerance to be maintained, and with the entire radio as near as possible to an ambient temperature of 26.5°C (79.8°F).

MASTR II ICOMs should be reset only when the frequency shows deviations in excess of the following limits:

- ± 0.5 PPM, when the radio is at 26.5° C (79.8°F).
- ± 2 PPM at any other temperature within the range of $-5\,^{\circ}C$ to $+55\,^{\circ}C$
- The specification limit (± 2 PPM or ± 5 PPM) at any temperature within the ranges of $-40\,^{\circ}\text{C}$ to $-5\,^{\circ}\text{C}$ ($-40\,^{\circ}\text{F}$ to $+23\,^{\circ}\text{F}$) or $+55\,^{\circ}\text{C}$ to $+70\,^{\circ}\text{C}$ $(+131^{\circ}F \text{ to } +158^{\circ}F)$.

If an adjustment is required, pry up the cover on the top of the ICOM to expose the trimmer, and use one of the following procedures:

If the radio is at an ambient temperature of 26.5°C (79.8°F), set the oscillator for the correct operating frequency.

If the radio is not at an ambient temperature of 26.5°C, setting errors can be minimized as follows:

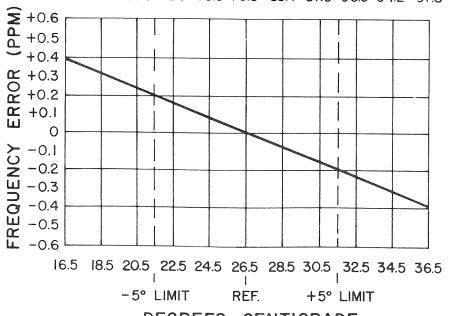
- To hold setting error to ± 0.6 PPM (which is considered reasonable for 5 PPM
 - 1. Maintain the radio at 26.5°C (± 5 °C) and set the oscillator to desired frequency, or-
 - 2. Maintain the radio at 26.5°C ($\pm10^{\circ}\text{C}$) and offset the oscillator, as a function of actual temperature, by the amount shown in Figure 9.
- To hold setting error to ± 0.35 PPM (which is considered reasonable for 2 PPM ICOMs): Maintain unit at $26.5\,^{\circ}\text{C}$ ($\pm 5\,^{\circ}\text{C}$) and offset the oscillator, as a function of actual temperature, by the amount shown in Figure 9.

For example: Assume the ambient temperature of the radio is 18.5°C (65.4°F). At that temperature, the curve shows a correction factor of 0.3 PPM. (At 25 MHz, 1 PPM is 25 Hz. At 50 MHz, 1 PPM is 50 Hz).

With an operating frequency of 50 MHz, set the oscillator for a reading of 15 Hz (0.3 x 50 Hz) higher than the licensed operating frequency. If a negative correction factor is obtained (at temperatures above 26.5°C), set the oscillator for the indicated PPM lower than the licensed operating frequency.

DEGREES FAHRENHEIT

61.8 65.4 69.0 72.6 76.6 79.8 83.4 87.0 90.6 94.2 97.8



DEGREES CENTIGRADE

RC-2453

Figure 9 - Frequency Characteristics Vs. Temperature

METERING JACK J205 POWER **ADJUST** R261 C143 -**EXCITER** METERING **JACK** J103 MOD **ADJUST** R127 CHANNEL **GUARD** MOD **ADJUST** R128

TEST PROCEDURES

These Test Procedures are designed to assist you in servicing a transmitter that is operating—but not properly. Problems encountered could be low power output, tone and voice deviation, defective audio sensitivity, and modulator adjust control set too high. Once a defect is pin-pointed,

refer to the "Service Check" and the additional corrective measures included in the Transmitter Troubleshooting Procedure. Before starting with the Transmitter Test Procedures, be sure the transmitter is tuned and aligned to the proper operating frequency.

CAUTION -

Before bench testing the MASTR II Mobile Radio, be sure of the output voltage characteristics of your bench power supply.

To protect the transmitter power output transistors from possible instant destruction, the following input voltages must not be exceeded:

Transmitter unkeyed: 20 Volts
Transmitter keyed (50 ohm resistive load): 18 Volts
Transmitter keyed (no load or non-resistive load): 15.5 Volts

These voltages are specified at the normal vehicle battery terminals of the radio and take the voltage drop of standard cables into account. The voltage limit shown for a non-optimum load is for "worst case" conditions. For antenna mismatches likely to be encountered in practice, the actual limit will approach the 18 Volt figure.

Routine transmitter tests should be performed at EIA Standard Test Voltages (13.6 VDC for loads of 6 to 16 amperes; 13.4 VDC for loads of 16 to 36 amperes). Input voltages must not exceed the limits shown, even for transient peaks of short duration.

Many commonly used bench power supplies cannot meet these requirements for load regulation and transient voltage suppression. Bench supplies which employ "brute force" regulation and filtering (such as Lapp Model 73) may be usable when operated in parallel with a 12-Volt automotive storage battery.

TEST EQUIPMENT REQUIRED

for test hookup as shown:

1. Wattmeter similar to: 2. VTVM similar to: 3. Audio Generator similar to:

Bird # 43 Jones # 711N Triplett # 850 Heath # IM-21 GE Model 4EX6Al0

4. Deviation Meter (with a .75 kHz scale) similar to:
Measurements # 720

5. Multimeter similar to:

GE TEST SET MODEL 4EX3A11, MODEL 4EX8K12 or 20,000 ohms-per-Volt voltmeter

POWER MEASU

TEST PROCEDURE

- 1. Connect transmitter output from the antenna jack to the wattmeter is terminated into a 50-ohm load.
- 2. Key the transmitter and check the wattmeter for the de

SERVICE CHECK

Check the setting of the Power Adjust Control (R261).

Refer to the QUICK CHECKS on the Transmitter Troublesh

VOICE DEVIATION, SYMMETRY

TEST PROCEDURE

- 1. Connect the test equipment to the transmitter as shown
- 2. In radios with Channel Guard, set Channel Guard Mod Ad
- 3. Set the Audio generator output to 1.0 VOLTS RMS and fr
- . Key the transmitter and adjust Deviation Meter to carr
- 5. Deviation reading should be ± 4.5 kHz in radios without Channel Guard.
- 6. If necessary, adjust MOD ADJUST control R127 for the p deviation, whichever is greater.

NOTES: -- MASTR II transmitters are adjusted for 4.5 kHz
The factory adjustment will prevent the transm
than 5.0 kHz under the worst conditions of free
temperature.

- 7. If the deviation reading plus (+) or minus (-) differs as shown in the Transmitter Alignment Chart.
- 8. Check Audio Sensitivity by reducing generator output without Channel Guard, or 2.25 kHz for radios with Channellivolts. If not, refer to the Transmitter Troubles

"Service Check" and the additional asures included in the Transmitter ng Procedure. Before starting with er Test Procedures, be sure the s tuned and aligned to the proper quency.

the output voltage

ssible instant des-

.5 Volts

terminals of the count. The voltage litions. For antenna limit will approach

of 16 to 36 amperes). cransient peaks of

requirements for load les which employ 73) may be usable battery.

rator similar to:

del 4EX6Al0

oltmeter

A11.

POWER MEASUREMENT

TEST PROCEDURE

- 1. Connect transmitter output from the antenna jack to the wattmeter through a 50-ohm coaxial cable. Make sure the wattmeter is terminated into a 50-ohm load.
- 2. Key the transmitter and check the wattmeter for the desired power output.

SERVICE CHECK

Check the setting of the Power Adjust Control (R261).

Refer to the QUICK CHECKS on the Transmitter Troubleshooting Procedure.

VOICE DEVIATION, SYMMETRY AND AUDIO SENSITIVITY

TEST PROCEDURE

- 1. Connect the test equipment to the transmitter as shown.
- 2. In radios with Channel Guard, set Channel Guard Mod Adjust R128 for zero tone deviation.
- 3. Set the Audio generator output to 1.0 VOLTS RMS and frequency to 1 kHz.
- 4. Key the transmitter and adjust Deviation Meter to carrier frequency.
- 5. Deviation reading should be ± 4.5 kHz in radios without Channel Guard, and ± 3.75 kHz in radios with Channel Guard.
- 6. If necessary, adjust MOD ADJUST control R127 for the proper deviation on plus (+) or minus (-) deviation, whichever is greater.
- NOTES: -- MASTR II transmitters are adjusted for 4.5 kHz deviation at the factory. The factory adjustment will prevent the transmitter from deviating more than 5.0 kHz under the worst conditions of frequency, voltage and temperature.
- 7. If the deviation reading plus (+) or minus (-) differs by more than 0.5 kHz, recheck Steps 1 and 2 as shown in the Transmitter Alignment Chart.
- 8. Check Audio Sensitivity by reducing generator output until deviation falls to 3.0 kHz for radios without Channel Guard, or 2.25 kHz for radios with Channel Guard. Voltage should be LESS than 120 millivolts. If not, refer to the Transmitter Troubleshooting Procedure.

TEST PROCED

- 1. Set up the
- 2. Remove the
- 3. Key the tra

NOTES:

- 1. On units su carefully d Alignment (
- 2. The Tone De is changed.

ter through a 50-ohm coaxial cable. Make sure wer output.

cocedure.

AUDIO SENSITIVITY

for zero tone deviation.

o 1 kHz.

ency.

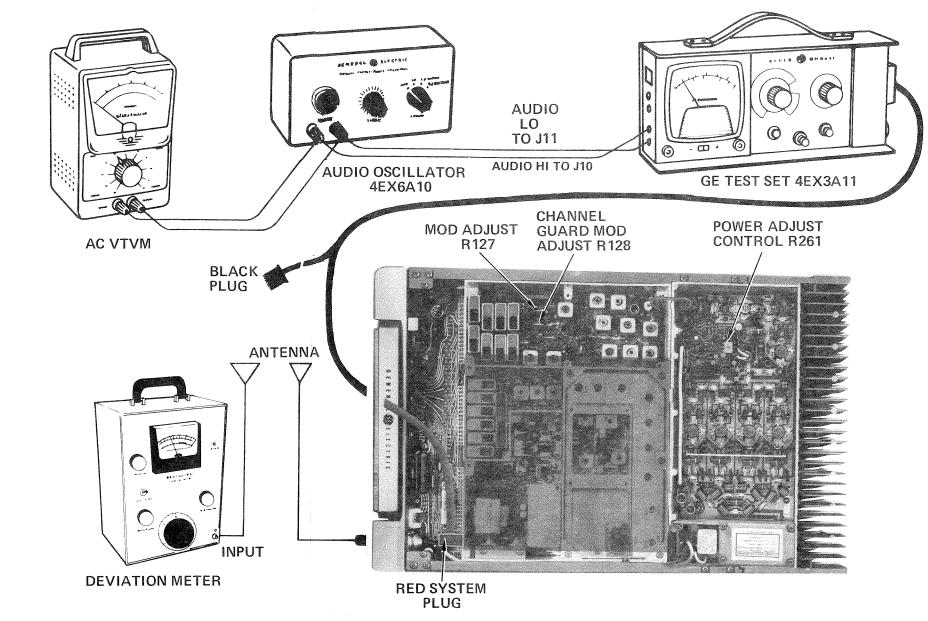
Guard, and ± 3.75 kHz in radios with

iation on plus (+) or minus (-)

n at the factory.
m deviating more
oltage and

than 0.5 kHz, recheck Steps 1 and 2

ation falls to 3.0 kHz for radios d. Voltage should be LESS than 120 rocedure.



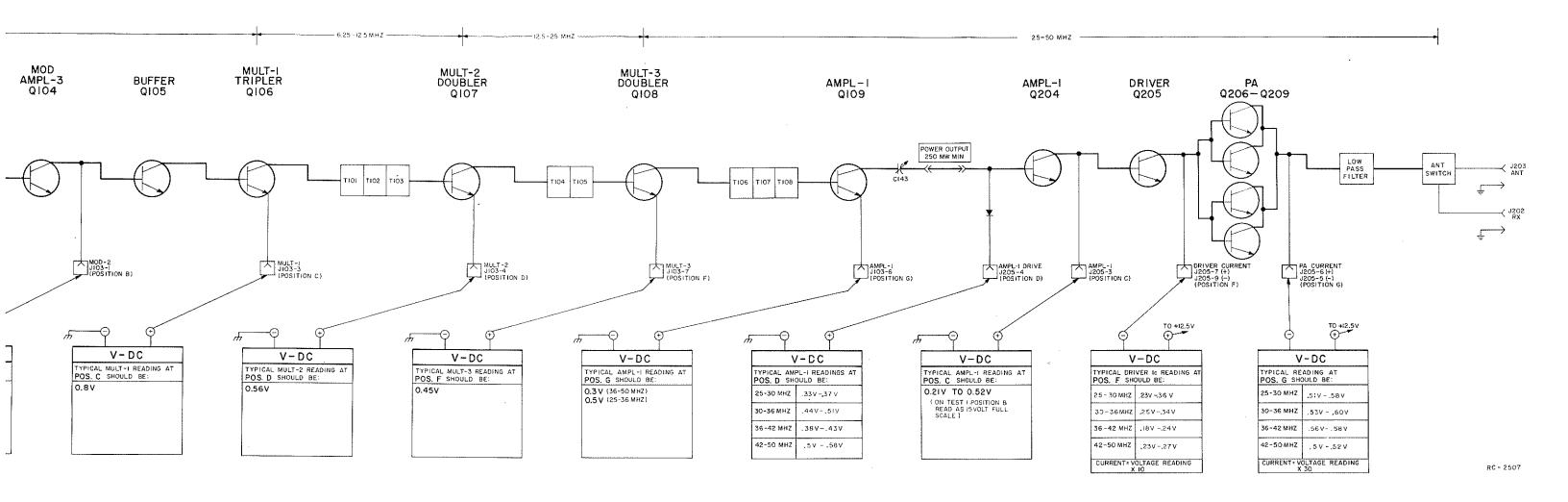
TONE DEVIATION WITH CHANNEL GUARD

TEST PROCEDURE

- 1. Set up the Deviation Meter and monitor the output of the transmitter.
- 2. Remove the 1000 Hz signal from the audio generator.
- 3. Key the transmitter and check for 0.75 kHz deviation. If the reading is low or high, adjust Channel Guard MOD ADJUST R128 for a reading of 0.75 kHz.

NOTES:

- 1. On units supplied with Channel Guard, the Phase Modulator Tuning should be adjusted carefully to insure proper performance. (Refer to Steps 1 and 2 in the Transmitter Alignment Chart).
- 2. The Tone Deviation Test Procedures should be repeated every time the Tone Frequency is changed.



TROUBLESHOOTING PROCEDURE

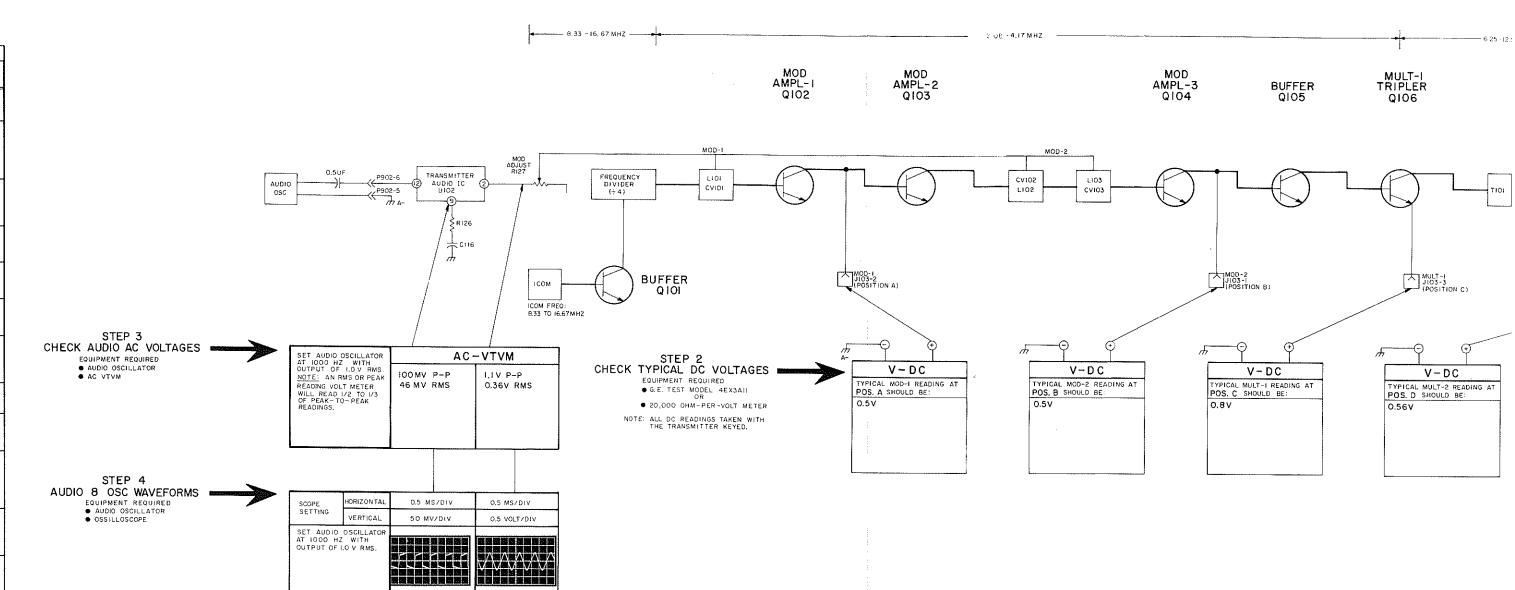
25-50 MHz, 100-WATT TRANSMITTER

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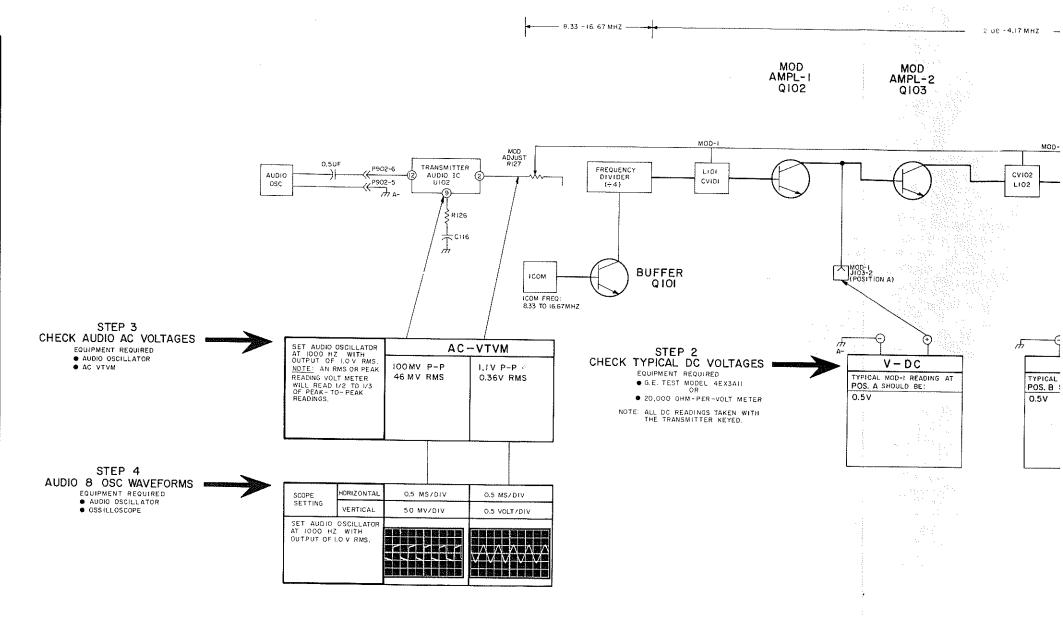
(S

ERO METER READING 101, U101, L101, R101, 10-Volt or or Channel or switch ground. 102, CV102, L103, CR104, Q104 }106, T101 1102, T103, Q107, 105, Q108, T106 1107, T108, Q109, out from Exciter, iter output, 2211, CR201 204, Check & C 1205, Q206-Q209 SWITCH K201

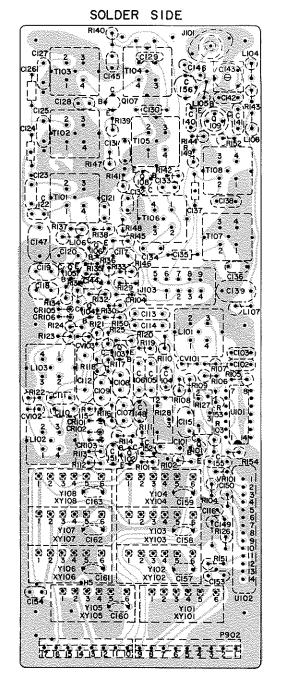


STEP I - QUICK CHECKS

METER	VE STAGE				
POSITION GE TEST SET	HIGH METER READING	LOW METER READING	ZERO METER READING		
<u> </u>	MADING		DALLARIA		
		EXCITER			
A (MOD-1)	Q102, 10- Volt regulator	Q102, CV101, L101, 10-Volt regulator	ICOM, Q101, U101, L101, Q102, CR101, 10-Volt regulator or Channel Selector switch ground.		
B (MOD-2)	Q104, 10- Volt regulator	Q103, L102, L103, CV102, CV103, Q104	Q103, L102, CV102, L103, CV103, CR104, Q104		
C (MULT-1)	Q105, Q106 T101	Q105, Q106	Q105, Q106, T101		
D (MULT-2)	Q107, T104	T101, T102, T103, Q107	T101, T102, T103, Q107, T104		
F (MULT-3)	Q108, T106	T104, T105, Q108	T104, T105, Q108, T106		
G (AMPL-1)	Q109, C146, R144	T106, T107, T108, Q109, L108	T106, T107, T108, Q109, L104, L107		
	P	OWER AMPLIFIER			
"D" (AMPL-1 DRIVE)		Low Output from Exciter	No output from Exciter, CR201		
"C" (AMPL-1 CONTROL VOLT- AGE)	Q217	Q217	No Exciter output, Q217, Q211, CR201		
"F" (DRIVER CURRENT)	Q205	Q205, Low Output from Q204	Q205, Q204, Check Pos. D & C		
"G" (PA CURRENT)	Q206, Q207 Q208, Q209	Q204, Q205, Q206—Q209	Q204, Q205, Q206-Q209 ANTENNA SWITCH K201		



EXCITER BOARD



COMPONENT SIDE

(19D423167, Sh. 2, Rev. 2) (19D423167, Sh. 3, Rev. 2)

(19D423167, Sh. 2, Rev. 2)

NOTE: LEAD ARRANGEMENT, AND NOT CASE SHAPE, IS DETERMINING FACTOR FOR LEAD IDENTIFICATION.

IN EIGHT-FREQUENCY EXCITERS (GROUPS 5-8), CAPACITORS C157-C163 ARE CLIPPED OUT AS REQUIRED TO MEET THE CUSTOMER REQUIREMENTS FOR FREQUENCIES. EXAMPLE; IF CUSTOMER WANTS ICOMS FOR FI; F2, F5, F7, THEN CAPACITORS C157, C160, AND C162 ARE CLIPPED OUT. C158, C159, C16‡, C163 ARE LEFT IN.

IN TWO-FREQUENCY EXCITERS (GROUPS 1-4) C157 IS CLIPPED OUT FOR COMBINATIONS WITH 2 TRANSMIT ICOMS. DA JUMPERS ARE PRESENT ON FREQUENCY SWITCHING LINES OF OTHER SIX ICOM CIRCUITS AS SHOWN.

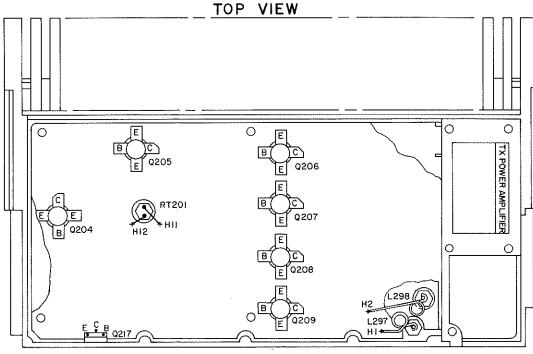
TION. (19D423234, Rev. 3)

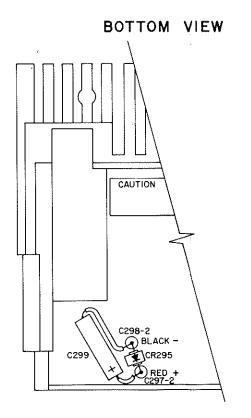
25-50 MHz, 100-WATT TRANSMITTER

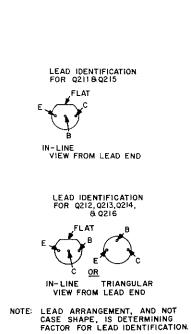
OUTLINE DIAGRAM

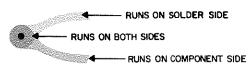
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PA ASSEMBLY









(19R622110, Rev. 7)

EXCITER BOARD

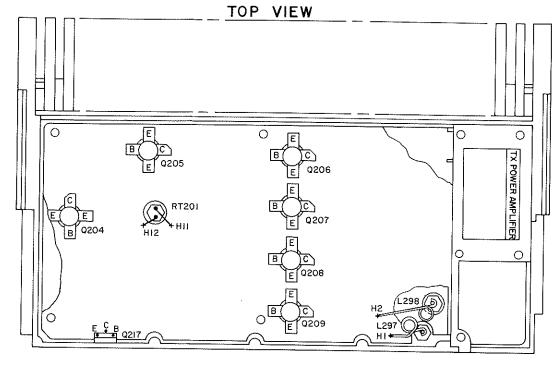
COMPONENT SIDE (19D423167, Sh. 2, Rev. 2) (19D423167, Sh. 3, Rev. 2)

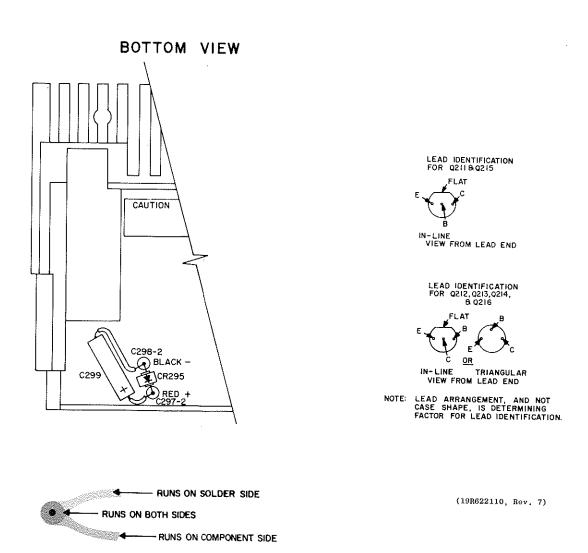
FREQUENCY EXCITERS (GROUPS 5-8), CAPACITORS 3 ARE CLIPPED OUT AS REQUIRED TO NEET THE FREQUENCIES. EXAMPLE: IF WANTS ICOMS FOR FI, FS, FT, THEN CAPACITORS 60, AND C162 ARE CLIPPED OUT. C158, C159, C161. LEFT IN.

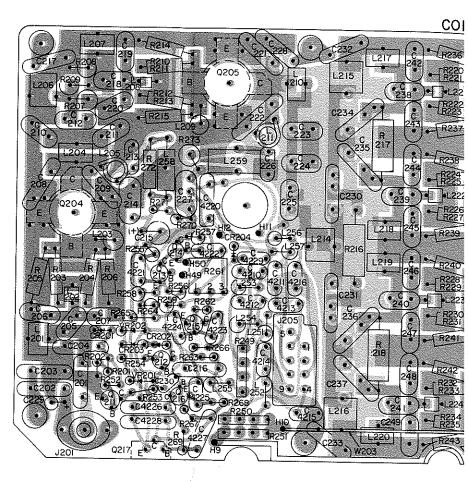
IN TWO-FREQUENCY EXCITERS (GROUPS 1-4) CIST IS CLIPPED OUT FOR COMBINATIONS WITH 2 TRANSMIT ICOMS. DA JUMPERS ARE PRESENT ON FREQUENCY SWITCHING LINES OF OTHER SIX ICOM CIRCUITS AS SHOWN.

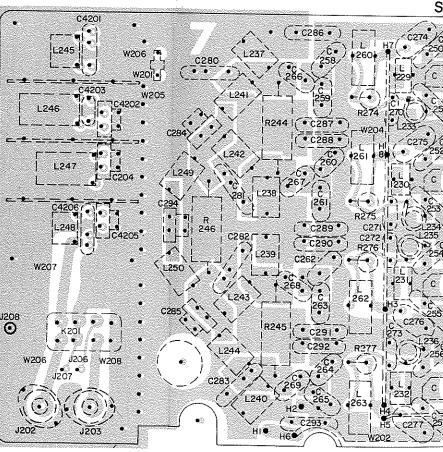
(19D423234, Rev. 3)

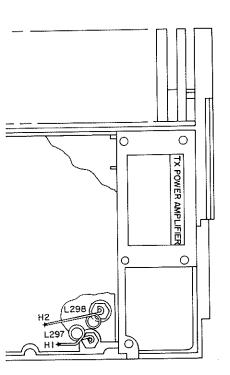
PA ASSEMBLY







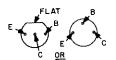




LEAD IDENTIFICATION FOR Q2118 Q215



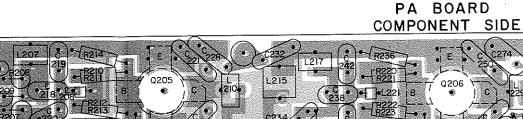
IN-LINE VIEW FROM LEAD END

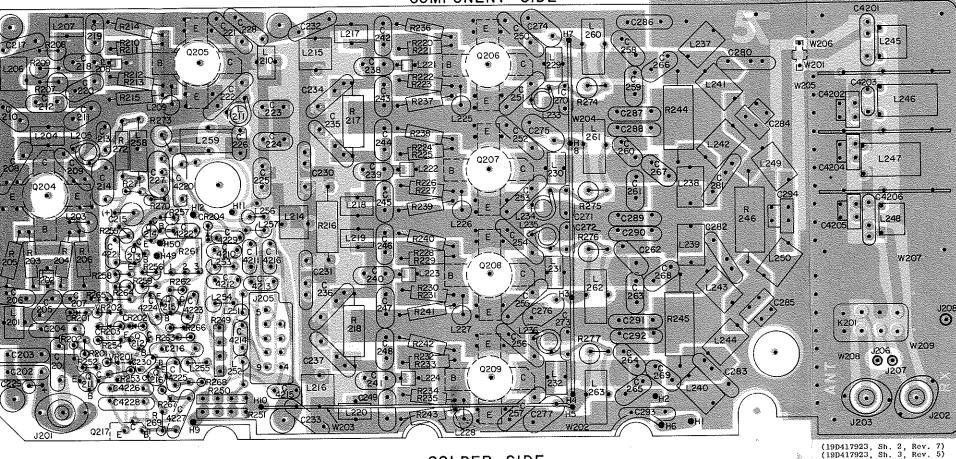


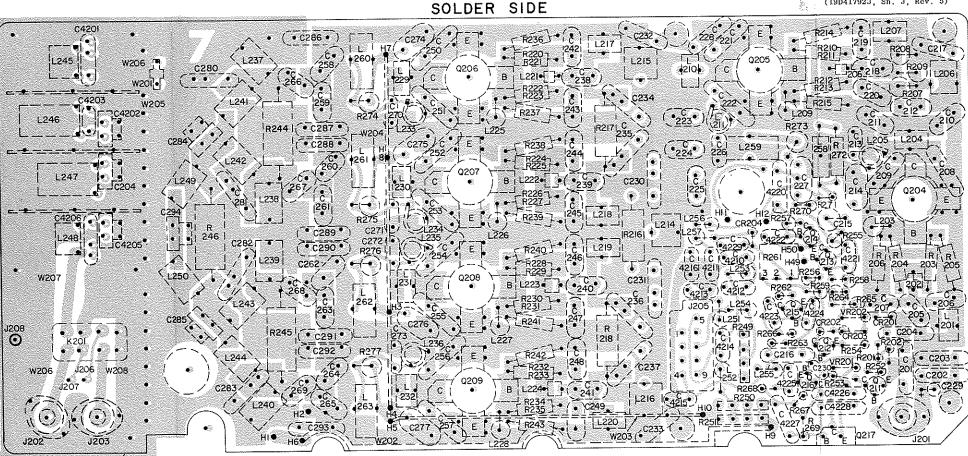
IN-LINE TRIANGULAR
VIEW FROM LEAD END

NOTE: LEAD ARRANGEMENT, AND NOT CASE SHAPE, IS DETERMINING FACTOR FOR LEAD IDENTIFICATION.

(19R622110, Rev. 7)







/MB0L	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
				-		TINGAL	100474074	G-41
15	19A700113P47	Composition: 220 ohms ±5%, 1/2 w.	R136	19A700113P63	Composition; 1K ohms ±5%, 1/2 w.	T104L*	19D416335G20	Coil.
16	19A700113P63	Composition: 1K ohms ±5%, 1/2 w.	R137	19A700113P27	Composition: 33 ohms ±5%, 1/2 w.		19D416635G13	In REV & earlier; Coil. includes;
17*	3R77P153K	Composition: 15K ohms ±10%, 1/2 w. Deleted by REV H.	R138	3R77P181K	Composition: 180 ohms ±10%, 1/2 w.		5493185P13	Tuning slug.
7LL*	3R77P203J	Composition: 20K ohms ±5%, 1/2 w.	R139	19A700113P41	Composition: 120 ohms ±5%, 1/2 w.	T104M*	19D416635G21	Coil.
		In REV H:	R140	19A700113P23	Composition: 22 ohms ±5%, 1/2 w.	110.11	100110000011	In REV E & earlier;
	3R77P303J	Composition: 30K ohms ±5%, 1/2 w. Added by REV H.	R141 R142	19A700113P35	Composition: 68 ohms ±5%, 1/2 w.		19D416635G5	Coil. Includes:
7L	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	R143LL	19A700113P23 3R77P101K	Composition: 22 ohms ±5%, 1/2 w. Composition 100 ohms ±10%, 1/2 w.		5493185P13	Tuning slug.
7 M	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	R143L	3R77P101K	Composition: 100 ohms $\pm 10\%$, 1/2 w.	T104H*	19D416335G22	Coil.
7H	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	R143M*	19A700113P19	Composition: 15 ohms ±5%, 1/2 w.			In REV E & earlier;
8	3R77P474K	Composition: 470K ohms ±10%, 1/2 w.		1011700110110	In REV G & earlier:		19D416635G5	Coil. Includes:
9	3R77P104K	Composition: 100K ohms ±10%, 1/2 w.		3R77P820K	Composition: 82 ohms ±10%, 1/2 w.		5493185P13	Tuning slug.
0	19A700113P95	Composition: 22K ohms ±5%, 1/2 w.	R143H	19A700113P37	Composition: 82 ohms ±5%, 1/2 w.	T105LL	19D416635G13	Coil. Includes:
1	19A700113P36	Composition: 75 ohms ±5%, 1/2 w.	R1441.L	19A700113P19	Composition: 15 ohms ±5%, 1/2 w.		5493185P13	Tuning slug.
2	19A700113P59	Composition: 680 ohms ±5%, 1/2 w.	R144L	19A700113P19	Composition: 15 ohms ±5%, 1/2 w.	T105L	19D416635G13	Coil. Includes:
3	19A700113P75	Composition: 3.3K ohms ±5%, 1/2 w.	R144M	19A700113P15	Composition: 10 ohms ±5%, 1/2 w.		5493185P13	Tuning slug.
4	3R77P511J	Composition: 510 ohms ±5%, 1/2 w.	R144H	19A700113P15	Composition: 10 ohms ±5%, 1/2 w.	T105M	19D416635G5	Coil, Includes:
5	3R77P473K	Composition: 47K ohms ±10%, 1/2 w. Composition: 560 ohms ±5%, 1/2 w.	R145	19A700113P99	Composition: 33K ohms ±5%, 1/2 w.		5493185P13	Tuning slug.
6	19A700113P57	Composition: 820 ohms ±5%, 1/2 w.	R146	19A700113P107	Composition: 68K ohms ±5%, 1/2 w.	Т105Н	19D416635G5	Coil. Includes;
7	19A700113P61	Composition: 820 dias £1%, 1/2 w. Composition: 2.2K ohms ±10%, 1/2 w.	R147	19A700113P99	Composition: 33K ohms ±5%, 1/2 w.		5493185P13	Tuning slug.
8	3R77P222K	Composition: 680 ohms ±5%, 1/2 w.	thru R150			T106LL	19D416835G14	Coil, Includes:
9	19A700113P59	Composition: 510 ohms ±5%, 1/2 w.	R151	19A700113P63	Composition: 1K ohms ±5%, 1/2 w.		5493185P13	Tuning slug.
0	3R77P511J 19A700113P95	Composition: 22K ohms ±5%, 1/2 w.	R152	19A700113P15	Composition: 10 ohms ±5%, 1/2 w.	T106L	19D416635G14	Coil. Includes:
2*	3R77P153K	Composition: 15% ohms ±10%, 1/2 w. Deleted by	R153	19A700113P63	Composition: 1K ohms ±5%, 1/2 w.		5493185P13	Tuning slug.
2-	SKITFISK	REV H.	and R154			T106M	19D416635G6	Coil. Includes:
							5493185P13	Tuning slug.
2LL*	3R77P2O3J	Composition: 20K ohms ±5%, 1/2 w.				Т106Н	19D418635G6	Coil, Includes:
		In REV H:	TlOlLL	19D416635G10	Coil. Includes:		5493185P13	Tuning slug.
	3R77P3O3J	Composition: 30K ohms ±5%, 1/2 w. Added by REV H.	l:	5493185P13	Tuning slug.	T107LL	19D416635G15	Coil. Includes:
2L	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	T101L	19D416635G10	Coil. Includes:		5493185P13	Tuning slug.
2 M	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.		5493185P13	Tuning slug,	T107L	19D416635G15	Coil. Includes;
2Н	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	TlOLM	19D416635G2	Coil. Includes:		5493185P13	Tuning slug.
3*	3R77P153K	Composition: 15K ohms ±10%, 1/2 w. Deleted by REV H.		5493185P13	Tuning slug.	T107M	19D416635G7	Coil. Includes:
31.L*	3R77P2O3J	Composition: 20K ohms ±5%, 1/2 w.	TlOlH	19D416635G2	Coil. Includes:		5493185P13	Tuning slug.
		In REV H:		5493185P13	Tuning slug.	Т107Н	19D416635G7	Coil. Includes:
	3R77P3O3J	Composition: 30K ohms ±5%, 1/2 w. Added by REV H.	T102LL	19D416635G11	Coil. Includes: Tuning slug.		5493185P13	Tuning slug.
31.	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	m1001	5493185P13 19D416635G11	Coil. Includes:	T108LL	19D416335G16	Coil. Includes:
3 M	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	T102L	5493185P13	Tuning slug.		5493185P13	Tuning slug.
эн	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	T102M	19D416635G3	Coil. Includes:	T108L	19D416635G16	Coil. Includes:
4	19A700113P95	Composition: 22K ohms ±5%, 1/2 w.	1102	5493185P13	Tuning slug.		5493185Pl3	Tuning slug.
:5	19A700113P63	Composition: 1K ohms ±5%, 1/2 w.	т102н	19D416635G3	Coil. Includes:	T108M	19D416335G8	Coil. Includes:
:6*	3R77P431J	Composition: 430 ohms ±5%, 1/2 w.	110211	5493185P13	Tuning slug.		5493185P13	Tuning slug.
		In REV D & earlier;	T103LL	19D416635G12	Coil. Includes:	т108н	19D416635G8	Coil. Includes:
	3R77P391K	Composition: 390 ohms ±10%, 1/2 w.		5493185P13	Tuning slug.		5493185Pl3	Tuning slug.
:7	19B209358P106	Variable, carbon film: approx 300 to 10,000 chms ±10%, 0.25 w; sim to CTS Type X-201.	T103L	19D416635G12	Coil. Includes:			INTEGRATED CIRCUITS
:8	19B209358P108	variable, carbon film: approx 2k to 50k ohms ±10%, 0.25 w; sim to CTS Type x-201.		5493185Pl3	Tuning slug.	Ų101	19A116842P1	Digital, High Speed TTL; Dual J-K Master-Slav Flip Flop; sim to SM54H73N.
19	19A700113P36	Composition: 75 ohms ±5%, 1/2 w.	T103M	19D416635G4	Coil. Includes:	U102	19D416542G2	Transmitter, Audio.
10	19A700113P59	Composition: 680 ohms ±5%, 1/2 w.		5493185P13	Tuning slug.			
11	19A700113P75	Composition: 3.3K ohms ±5%, 1/2 w.	T103H	19D416635G4	Coil. Includes:			
32	3R77P511J	Composition: 510 ohms ±5%, 1/2 w.	[:	5493185P13	Tuning slug.	VR101	4036887P56	Zener: 500 mH, 5.0 v. nominal.
33	3R77P473K	Composition: 47K ohms ±10%, 1/2 w.	Т1041+	19D416635G19	Coil.			
34	19A700113P57	Composition: 560 ohms ±5%, 1/2 w.			In REV E & earlier:			
35	19A700113P95	Composition: 22K ohms ±5%, 1/2 w.		19D416635G13	Coil. Includes:			
				5493185P13	Tuning slug.			
					+			
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SYMBOL	GE PART NO.	DESCRIPTION
XY101 thru XY108	19a701785P1	NOTE: when reordering, specify quantity. Contact, electrical.
	19A121252P1 19A129424G2 4036555P1 4029006P3	Heat sink. (Used with Q109). Can. (Used with T101-T108 & L101-L103). Insulator, washer: nylon. (Used with Q109). Clip, compression: 375 x 0.19 x .02 inches; sim to Tinnerman Products C5426-014-24. (Used with Q109).
		ASSOCIATED ASSEMBLIES
Yl01 thru Yl08 Yl01 thru Yl08	19A129393G13 19A129393G16	Compensated: 2 PPM, 25-50 MHz. Externally Compensated: 5 PPM, 25-50 MHz.

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter," which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

19D416659G1-0

- REV. A To incorporate an improved transistor. Changed Q107.
- REV. B To increase power output. Changed C146* and added C156.
- REV. C To increase drive to modulator. Changed Q101 and R102.
- REV. D To provide RF bypassing on unused frequency selection leads.
 Added C157 thru C163.
- REV. E To increase audio sensitivity. Changed R126.
- REV. F To eliminate possible shorting of shield to wire runs on printed wire board. Changed TlO4LL, TlO4L, TlO4M and TlO4H. Deleted shield (198219619P1), Cl29LL, Cl29L, Cl29M and Cl29H.

19D416659G4 & G8

REV. G - To improve multi-frequency spread performance in cold temperatures. Changed Cl30H.

19D416659G3 & G7

- REV. G To improve multi-frequency spread performance with high humidity. Changed Cl30.
- REV. H To improve spurious and stability performance. Physically changed (swapped) positions of L201 and C205.
- REV. G 19D416659G1, G2, G5, G6
- REV. J 19D416659G3, G7
- REV. H 19D416659G4, G8
 - To increase exciter output. Changed Q109.

REV. H - 19D416659G1, G5

To increase Channel Guard deviation at the low end of the split. Deleted R107, R122 and R123. Added R107LL, R122LL and R123LL.

REV. J - 19D416659G1, G5

To meet symmetry specs. Changed R107LL, R122LL and R123LL.

	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYN
	C125M	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCm, temp coef	C137M	19470001328	Phenolic: 0.39 pf ±5%, 500 YDC%.	J103	19B219374G1	Connector, Includes:	R105	19A700113P47	Composition: 220 ohms ±5%, 1/2 w.	R136
			-80 PPM.	C137H	19A700013F8	Phenolic: 0.39 pf ±5%, 500 VDCw.		19A116651P1	Contact, electrical: sim to Malco XO-2864.	R106	19A700113P63	Composition: 1K ohms ±5%, 1/2 w.	R137
	C125H	5496219P254	Ceramic disc: 43 pf ±5%, 500 VDCm, temp coef -80 PPM.	C138LL	5496219P243	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef				R107*	3R77P153K	Composition: 15K ohms ±10%, 1/2 w. Deleted by REV H.	8138
	C12617	5491601P124	Phenolic: 1.8 pf ±5%, 500 VDCW.			-80 PPM.	T1011T	19D416635G9	Coil.	R107111*	3R77P203J	Composition: 20K ohms ±5%, 1/2 w.	R139
-	C126L	5491601P124	Phenolic: 1.8 pf ±5%, 500 VDCW.	C138L	5496219P240	Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCw, temp coef -80 PPM.	LioiL	19D416635G17	Coil.			In REV H:	R140
	C126M	19A700013P14	Phenolic: 1.2 pf ±5%, 500 VDCW.	C138M	5496219P242	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef	TTOIM	19D416635G1	Coil.		3R77P303J	Composition: 30K ohms ±5%, 1/2 w. Added by REV H.	R141
	C126H	19A700013P14	Phenolic: 1.2 pf ±5%, 500 VDCw.	C138H	5496219P238	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCw, temp	TIOIH	19D416635G18	Coil.	R107L	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	R142
	C127LL	5496219P262	Ceramic disc: 91 pf ±5%, 500 VDCw, temp coef -80 PPM.	2200	10411400000100	coef -80 PPM.	F105FF	19D4 16635G9	Coil.	R107M	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	R143
	C127L	5496219P258	Ceramic disc: 62 pf ±5%, 500 VDCm, temp coef	C139	19A116080P107	Polyester: 0.1 µf ±20%, 50 VDCm. Ceramic disc: 1000 pf ±20%, 1000 VDCm; sim to	L102L	19D416635G17	Coil.	R107H	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	K143
			-80 PPM.	C140	19A116655P19	RMC Type JF Discap.	L102M	19D416635Gl	Coil.	R108	3R77P474K	Composition: 470K ohms ±10%, 1/2 w.	R143
	C127M	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef -80 PPM.	C141LL	5490008P127	Silver mica: 100 pf ±10%, 500 VDCh; sim to flectro Motive Type DM-15.	ь102н	19D416635G18	Coil.	R109	3R77P104K	Composition: 100K ohms ±10%, 1/2 w.	
	C127H	5496219P254	Ceramic disc: 43 pf ±5%, 500 VDCm, temp coef	C141L	5490008P125	Silver mica: 82 pf ±10%, 500 VDCw; sim to	L1031.L	19D416635G9	Coil.	R110	19A700113P95	Composition: 22K ohms ±5%, 1/2 w.	1
	-100	10+114000N1	-80 PPM. Polyester: 0.01 µf ±20%, 50 VDCW.	"		Electro Motive Type DM-15.	L103L	19D416635G17	Coil.	Rlll	19A700113P36	Composition: 75 ohms ±5%, 1/2 w.	R143
	C128	19A116080P1 5496219P255	Ceramic disc: 47 pf ±5%, 500 VDCw, temp coef	C141#	5490008P131	Silver mica: 150 pf ±10%, 500 VDCw; sim to Electro Motive Type DM-15.	TJ03W	19D416635G1	Coil.	R112	19A700113P59	Composition: 680 ohms ±5%, 1/2 w.	R144
	C129LL*	3496219F233	-80 PPM. Deleted by REV F.			In REV G & earlier;	L103H	19D416635G18	Coil.	R113	19A700113P75	Composition: 3.3K obms ±5%, 1/2 w.	R144
	C129L*	5496219P251	Ceramic disc: 33 pf ±5%, 500 VDCw, temp coef -80 PPM. Deleted by REV F.		5490008P123	Silver mica: 68 pf ±10%, 500 VDCW; sim to	1.1041.1.	19A700000P16	Choke, RF: 2.7 μh ±10%, 1.20 ohms DC res max.	R114	3R77P51lJ	Composition: 510 ohms ±5%, 1/2 w.	R144 R144
	C129M*	5496219P247	Ceramic disc: 22 pf ±5%, 500 VDCw, temp coef			Electro Motive Type DM-15.	L104L	19A700000P15	Choke, RF: 2.20 µh ±10%, 0.97 ohms DC res max.	R115	3R77P473K	Composition: 47K ohms ±10%, 1/2 w.	R145
	01232		-80 PPM. Deleted by REV F.	C141H	5490008P127	Silver mica: 100 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.	L104M*	19A700000P6	Choke, RF: 0.33 µh ±10%, 0.07 ohms DC res max.	R116	19A700113P57	Composition: 560 ohms ±5%, 1/2 w.	R146
	C129H*	5496219P244	Ceramic disc: 15 pf ±5%, 500 VDCH, temp coef -80 PPM. Deleted by REV F.	C142LL	5490008P27	Silver mica: 100 pf ±50%, 50 VDCW; sim to Electro			In REV G & earlier:	R117	19A700113P61	Composition: 820 ohms ±5%, 1/2 w.	R147
	C130TT	19A700013P9	Phenolic: 0.47 pf ±5%, 500 VDCm.	01401	#400000B75	Motive Type DM-15. Silver mica: 82 pf ±5%, 500 VDCW; sim to Electro		7488079P7	Choke, RF: 1.50 µh ±10%, 0.50 ohms DC res max; sim to Jeffers 4411-10K.	R118	3R77P222K	Composition: 2.2K ohms ±10%, 1/2 w.	thru R150
1 1	C130L	5491601P110	Phenolic: 0.36 pf ±5%, 500 VDCh.	C142L	5490008P25	Motive Type DM-15.	L104H	19A700000P14	Choke, RF: 1.5 µh ±10%, 0.485 ohms DC res max.	R119	19A700113P59	Composition: 680 ohms ±5%, 1/2 w.	R151
	C130M*	19A700013P7	Phenolic: 0.33 pf ±5%, 500 VDCw.	C142M	5490008P25	Silver mica: 82 pf ±5%, 500 VDCH; sim to Electro Motive Type DM-15.	L105LL	19A700000P12	Choke, RF: 1.0 µh ±10%, 0.29 ohms DC res max.	R120	3R77P511J	Composition: 510 ohms ±5%, 1/2 w.	R152
			In REV F & earlier:	C142H	5490008P24	Silver mica: 75 pf ±5%, 500 VDCW; sim to Electro	L105L	19A700000P10	Choke, RF: 0.68 µh ±10%, 0.15 ohms DC res max.	R121 R122*	19A700113P95 3R77P153K	Composition: 22K ohms ±5%, 1/2 w. Composition: 15K ohms ±10%, 1/2 w. Deleted by	R153
		5491601P107	Phenolic: 0.27 pf ±5%, 500 VDCh.	02.2		Motive Type DM-15.	£105M	19A700000P8	Choke, RF: 0.47 µh ±10%, 0.09 ohms DC res max.	RIZZT	347772334	REV H.	and R154
	C130H*	19A700013PG	Phenolic: 0.27 pf ±5%, 500 VDCW. In REV F & earlier:	C143	19A116163P5 5494481P105	Variable: approx 5 to 60 pf, 50 VDCW; sim to Amperex 2222-809-08003. Ceramic disc: 330 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	L105H L106 and L107	19A700000P6	Choke, RF: 0.33 µh ±10%, 0.07 ohms DC res max. Choke, RF: 10.0 µh ±10%, 0.605 ohms DC res max.	R122LL*	3R77P303J	Composition: 20K ohms ±5%, 1/2 w. In REV H: Composition: 30K ohms ±5%, 1/2 w. Added by REV H.	T101
		5491601P105	Phenolic: 0.22 pf ±5%, 500 VDCW.	C145	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCm.	L108	19A700000₽14	Choke, RF: 1.50 µh ±10%, 0.48 ohms DC res max.	R122L	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	T101
	C131LL	5496219P255	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef -80 PPM.	C146*	5496219P238	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCW, temp				R122M	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	
	CIBIL	5496219P251	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef			coef -80 PPM. Added by REV B. Ceramic: 12 pf, ±5%, 0 PPM. Deleted by REV B.				R122H	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	T101
			-80 РРМ.	C146LL*	19A116656P12J8	Ceramic: 12 pf, 15%, 0 PPM. Deleted by REV B.	P902		Includes:	R123*	3R77P153K	Composition; 15K ohms ±10%, 1/2 w. Deleted by	
	C131M	5496219P247	Ceramic disc: 22 pf ±5%, 500 VDCw, temp coef -80 PPM.	C146L*	19A116656P12J8 19A116656P13J8	Ceramic: 13 pf, ±5%, 0 PPM. Deleted by REV B.		19B219594P2	Contact strip: 8 pins.			REV H.	T 10:
	С131Н	5496219P244	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef	C146M* C146H*	19A116656P12J8	Ceramic: 12 pf, ±5%, 0 PPM. Deleted by REV B.		19B219594P3	Contact strip: 9 pins.	R123LL*	3R77P2O3J	Composition: 20K ohms ±5%, 1/2 w. In REV H:	
			-80 PPM. Polyester: 0.01 µf ±20%, 50 VDCW.	C146A+	19A116080P107	Polyester: 0.1 µf ±20%, 50 VDCW.					3R77P303J	Composition: 30K ohms ±5%, 1/2 w. Added by REV H.	T10:
1 1	C132 and	19Al16080Pl	Polyester: 0.01 pl 120%, 30 them.	C148	5494481P105	Ceramic disc: 330 pf ±20%, 1000 VDCw; sim to	Q101*	19A115330P1	Silicon, NPN.	n 1001	19A700113P91	Composition: 15K ohms ±5%, 1/2 w.	
1 1	C133	5496219P243	Ceramic disc: 13 pf ±5%, 500 VDCN, temp coef	****		RMC Type JF Discap.			In REV C & earlier:	R123L R123H	19A700113P91	Composition: 15% ohms ±5%, 1/2 w.	T10:
	C134LL	042001212123	-80 РРМ.	C149	5496267P10	Tantalum: 22 µf ±20%, 15 VDCW; sim to Sprague Type 150D.		19A115910P1	Silicon, NPN; sim to Type 2N3904.	R123H	19A700113P91	Composition: 15% ohms ±5%, 1/2 w.	
	C134L	5496219P240	Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM.	C150	5496267P14	Tantalum: 15 µf ±20%, 20 VDCw; sim to Sprague	Q102 thru	19A115330P1	Silicon, NPN.	R124	19A700113P95	Composition: 22K ohms ±5%, 1/2 w.	T10:
	C134M	5496219P242	Ceramic disc: 12 pf ±5%, 500 VDCw, temp coef		_,,,,,	Type 150D. Ceramic disc: 330 pf ±20%, 1000 VDCW; sim to	Q106			R125	19A700113P63	Composition: 1K ohms ±5%, 1/2 w.	
			-80 PPM,	C151	5494481P105	RMC Type JF Discap.	Q107*	19A115328Pl	Silicon, NPN.	R126*	3R77P431J	Composition: 430 ohms ±5%, 1/2 w.	T10:
	C134H	5496219P238	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCw, temp coef -80 PPM.	C152	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCm.		1	Earlier than REV A:			In REV D & earlier;	
	C135 <i>L</i> .L	19A700013P11	Phenolic: 0.68 pf ±5%, 500 VDCW.	thru C155				19A115330Pl	Silicon, NPN.		3R77P391K	Composition: 390 ohms ±10%, 1/2 w.	T10
- 1 1	C135L	5491601P114	Phenolic: 0.51 pf ±5%, 500 VDCw.	C156*	19A116867Pl	Variable, ceramic: 2.5-6 pf, +50% -10%, 160 VDCW; sim to 7-S-TRIKO-02. Added by REV B.	Q108	19A115328P1	Silicon, NPN. Silicon, NPN; sim to Type 2N4427.	R127	19B209358Pl06	Variable, carbon film: approx 300 to 10,000 ohms ±10%, 0.25 w; sim to CTS Type X-201.	T10
	C135M	19A700013P10	Phenolic: 0.56 pf ±5%, 500 VDCW.	C157*	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCm. Added by REV C	Q109*	19A116868P1	1	R128	19B209358P108		
	C135H	19A700013P9	Phenolic: 0.47 pf ±5%, 500 VDCW.	thru C163*					In G1,G2,G5,G6 of REV F & earlier: In G3,G7 of REV H & earlier: In G4,G8 of REV G & earlier:	1 1 11.25	150200001100	Variable, carbon film: approx 2K to 50K ohms ±10%, 0.25 w; sim to CTS Type X-201.	T10
	C136LL	5496219P243	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -80 PPM.		,			19A115329P2	Silicon, NPN.	R129	19A700113P36	Composition: 75 ohms ±5%, 1/2 w.	
	C136L	5496219P240	Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCw, temp	CR101	19A115250P1	Silicon, fast recovery, 225 mA, 50 PIV.				R130	19A700113P59	Composition: 680 ohms ±5%, 1/2 w.	T10
	C100F1	2420272474	coef -80 PPM.	thru CR106					RESISTORS	R131	19A700113P75	Composition: 3.3K ohms ±5%, 1/2 w.	
	C136M	5496219P242	Ceramic disc: 12 pf ±5%, 500 VDCw, temp coef -80 PPM.	CV101	5495769P12	Silicon, capacitive.	R101	19A700113P57	Composition: 560 ohms ±5%, 1/2 w.	R132	3R77P511J	Composition: 510 ohms ±5%, 1/2 w.	TlC
	С136Н	5496219P238	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCW, temp	thru CV103			R102*	19A700106P83	Composition: 6.8K ohms ±5%, 1/4 w.	R133	3R77P473K	Composition: 47K ohms ±10%, 1/2 w.	
	, 		coef -80 PPM.			JACKS AND RECEPTACLES			In REV C & earlier:	R134	19A700113P57	Composition: 560 ohms ±5%, 1/2 w.	
	C137LL	5491601P114	Phenolic: 0.51 pf ±5%, 500 YDCW.	J101	19A130924G1	Connector, receptacles; sim to Cinch 14H11613.		3R77P393K	Composition: 39K ohms ±10%, 1/2 w.	R135	19A700113P95	Composition: 22K ohms ±5%, 1/2 w.	
	C137L	5491601P114	Phenolic: 0.51 pf ±5%, 500 YDCW.				R103	19A700113P55	Composition: 470 ohms ±5%, 1/2 w.				
							R104	19A700113P35	Composition: 68 obms ±5%, 1/2 w.				
L				L	L	<u> </u>				. ——	1		

NGES

PARTS LIST

LB14440L

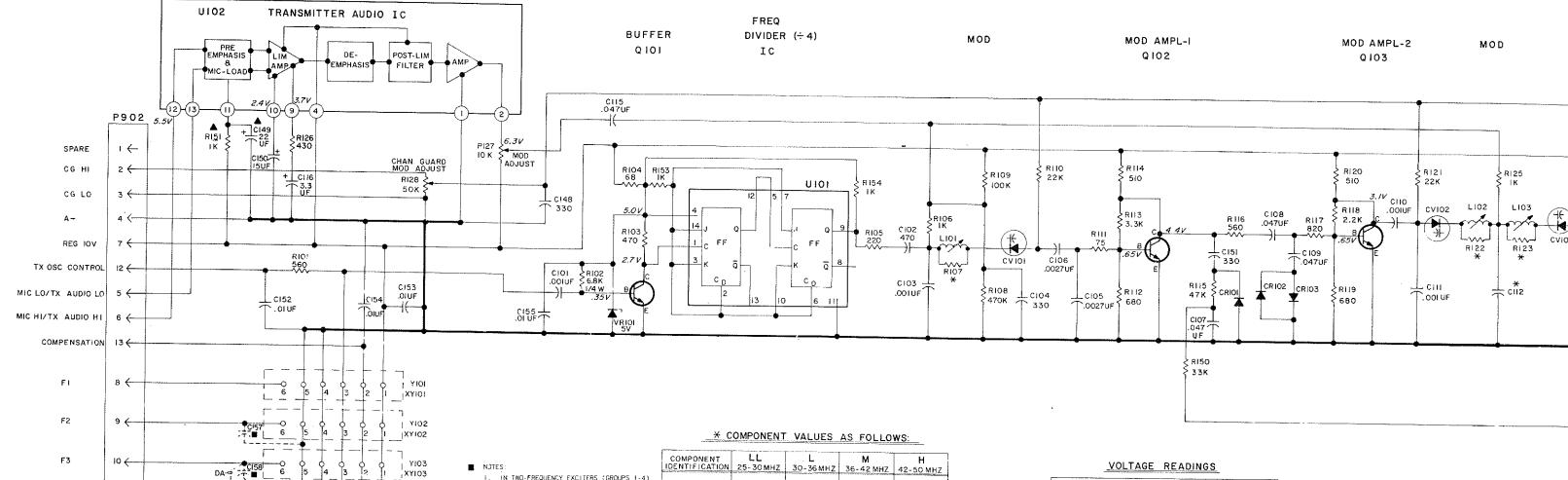
25-50 MHz EXCITER 19D416659G1-G8

SYMBOL	GE PART NO.	DESCRIPTION
		19D416659G1 2 FREQ 25-30 MHz (LL) 19D416659G2 2 FREQ 30-36 MHz (L) 19D416659G3 2 FREQ 36-42 MHz (M) 19D416659G4 2 FREQ 42-50 MHz (H) 19D416659G5 8 FREQ 25-30 MHz (LL) 19D416659G7 8 FREQ 30-36 MHz (L) 19D416659G8 8 FREQ 36-42 MHz (M) 19D416659G8 8 FREQ 42-50 MHz (H)
C101	19A116655P19	Ceramic disc; 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C102	19A116655P13	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C103	19All6655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCw; sim to RMC Type JF Discap.
C104	5494481P105	Ceramic disc: 330 pf ±20%, 1000 VDCm; sim to RMC Type JF Discap.
C105 and C106	19All6655P21	Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C107 thru	19A116080P105	Polyester: 0.047 μf ±10%, 50 VDCw.
C109 C110 and C111	19Al16655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
011011	40300039104	\$41,000 mton; (200 mt ±100) (500 MD0H; -2- t-
C112LL	4029003P104	Silver mica: 680 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-20.
C112L	4029003P104	Silver mica: 680 pf ±10%, 500 VDCN; sim to Electro Motive Type DM-20.
C112M	5493367P1000K	Mica: 1000 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-20.
С112Н	5493367P1000K	Mica: 1000 pf ±10%, 100 VDCw; sim to Electro Motive Type DM-20.
C113 and C114	19A116655P21	Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C115	19A116080P105	Polyester: 0.047 µf ±10%, 50 VDCm.
C116	5496267 P 9	Tantalum: 3.3 μ f $\pm 20\%$, 15 VDCw; sim to Sprague Type 150D.
0117 thru 0119	19116080P105	Polyester: 0.047 μf ±10%, 50 VDCW.
C120	5490008Pl39	Mica: 330 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.
C121 and C122	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCW.
С123LL	549621 9 P262	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef -80 PPM.
C123L	5496219P258	Ceramic disc: 62 pf ±5%, 500 VDCW, temp coef -80 PPM.
C123M	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef -80 PPM.
С123Н	5496219P254	Ceramic disc: 43 pf ±5%, 500 VDCW, temp coef -80 PPM.
:124LL	19A700013P15	Phenolic: 1.5 pf ±5%, 500 VDCW.
124L	19A700013P13	Phenolic: 1.0 pf ±5%, 500 VDCW.
2124M	19A700013P13	Phenolic: 1.0 pf ±5%, 500 VDCW.
:124н	19A700013P12	Phenolic: 0.82 pf ±5%, 500 VDCw.
C1251.L	5496219P262	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef -80 PPM.
C125L	5496219P258	Ceramic disc: 62 pf ±5%, 500 VDCH, temp coef

SYMBOL	GE PART NO.	DESCRIPTION
125M	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCw, temp coef -80 PPM.
125Н	5496219P254	Ceramic disc: 43 pf ±5%, 500 VDCm, temp coef
12614	5491601P124	Phenolic: 1.8 pf ±5%, 500 VDCW.
126L	5491601P124	Phenolic: 1.8 pf ±5%, 500 VDCw.
126M	19A700013P14	Phenolic: 1.2 pf ±5%, 500 VDCw.
126H	19A700013P14	Phenolic: 1.2 pf ±5%, 500 VDCW.
127 LL	5496219P262	Ceramic disc: 91 pf ±5%, 500 VDCw, temp coef -80 PPM.
127L	5496219P258	Ceramic disc: 62 pf ±5%, 500 VDCW, temp coef -80 PPM.
C127M	5496219P257	Ceramic disc; 56 pf ±5%, 500 VDCw, temp coef -80 PPM.
С127Н	5496219P254	Ceramic disc: 43 pf ±5%, 500 VDCH, temp coef -80 PPM.
128	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCW.
129 <i>LL</i> *	5496219P255	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef -80 PPM. Deleted by REV F.
C129L*	5496219P251	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -80 PPM. Deleted by REV F.
:129M*	5496219P247	Ceramic disc: 22 pf ±5%, 500 VDCW, temp coef -80 PPM. Deleted by REV F.
129H*	5496219P244	Ceramic disc: 15 pf ±5%, 500 VDCw, temp coef -80 PPM. Deleted by REV F.
:130LL	19A700013P9	Phenolic: 0.47 pf ±5%, 500 VDCh.
130L	5491601P110	Phenolic: 0.36 pf ±5%, 500 VDCW.
:130M*	19A700013P7	Phenolic: 0.33 pf ±5%, 500 VDCW.
	5491601P107	In REV F & earlier: Phenolic: 0.27 pf ±5%, 500 VDCh.
2130H*	19A700013P6	Phenolic: 0.27 pf ±5%, 500 VDCw.
	5401601010E	In REV F & earlier:
:131LL	5491601P105 5496219P255	Phenolic: 0.22 pf ±5%, 500 VDCW. Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef
131L	5496219P251	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef
:131M	5496219P247	-80 PPM. Ceramic disc: 22 pf ±5%, 500 VDCw, temp coef
:131Н	5496219P244	-80 PPM. Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef
:132	19A116080P1	-80 PPM. Polyester: 0.01 µ1 ±20%, 50 VDCh.
nd :133		,
134LL	5496219P243	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -80 PPM.
134L	5496219P240	Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM.
134M	5496219P242	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef -80 PPM.
:134н	5496219P238	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCh, temp coef -80 PPM.
13514	19A700013P11	Phenolic: 0.68 pf ±5%, 500 VDCW.
135L	5491601P114	Phenolic: 0.51 pf ±5%, 500 VDCw.
[19A700013P10	Phenolic: 0.56 pf ±5%, 500 VDCw.
135M	19A700013P9	Phenolic: 0.47 pf ±5%, 500 VDCW.
	13410001313	
135н	5496219P243	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -80 PPM.
135M 135H 136LL 136L		Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -80 PPM. Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM.
1361L	5496219P243	-80 PPM. Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCw, temp
:135H :136LL :136L	5496219P243 5496219P240	-80 PPM. Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCw, temp coof -80 PPM. Ceramic disc: 12 pf ±5%, 500 VDCw, temp coef
135H 136L 136M	5496219P243 5496219P240 5496219P242	-80 PPM. Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCw, temp coof -80 PPM. Ceramic disc: 12 pf ±5%, 500 VDCw, temp coef -80 PPM. Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCw, temp

	SYMBOL	GE PART NO.	DESCRIPTION	SYME
	C137M	19A700013P8	Phenolic: 0.39 pf ±5%, 500 VDC%.	J103
	C137H	19A700013P8	Phenolic: 0.39 pf ±5%, 500 VDCw.	
	C138LL	5496219P243	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -80 PPM.	
	C138F	5496219P240	Ceramic disc: 9.0 pf ±0.25 pf, 500 VDCw, temp coef -80 PPM.	F101F
	C138W	5496219P242	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef	Lioin
	C138H	5496219 P 238	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCw, temp coef -80 PPM.	ттотн
	C139	19A116080P107	Polyester: 0.1 µf ±20%, 50 VDCw.	170517
	C140	19All6655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.	L102L L102M
	C1411.L	5490008P127	Silver mica: 100 pf ±10%, 500 VDCh; sim to Electro Motive Type DM-15.	L102H
	C141L	5490008P125	Silver mica: 82 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.	F103FT
	C141M*	5490008P131	Silver mica: 150 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.	L103L
			In REV G & earlier:	L103H
		5490008P123	Silver mica: 68 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.	L1041L
	C14 lH	5490008P127	Silver mica: 100 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.	L104L L104M*
-	C1421L	5490008P27	Silver mica: 100 pf ±50%, 50 VDCW; sim to Electro Motive Type DM-15.	
	C142L	5490008P25	Silver mica: 82 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	
	C142M	5490008P25	Silver mica: 82 pf ±5%, 500 VDCW; sim to Electro	L104H L105LL
	C142H	5490008P24	Motive Type DM-15. Silver mica: 75 pf ±5%, 500 VDCW; sim to Electro	L105L
			Motive Type DM-15.	1105M
	C143	19A116163P5	Variable: approx 5 to 60 pf, 50 VDCW; sim to Amperex 2222-809-08003.	L105H
	C144	5494481P105	Ceramic disc: 330 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	L106 and L107
١	C145	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCW.	£108
	C146*	5496219P238	Ceramic disc: 7.0 pf ±0.25 pf, 500 VDCW, temp coef -80 PPM. Added by REV B.	
	C146LL*	19Al16656P12J8	Ceramic: 12 pf, ±5%, 0 PPM. Deleted by REV B.	P902
l	C146L*	19A116656P12J8	Ceramic: 12 pf, ±5%, 0 PPM. Deleted by REV B.	
l	C146M*	19A116656P13J8	Ceramic: 13 pf, ±5%, 0 PPM. Deleted by REV B. Ceramic: 12 pf, ±5%, 0 PPM. Deleted by REV B.	
	C146h-	19A116356P12J8 19A116080P107	Ceramic: 12 pf, ±5%, 0 PPM. Deleted by REV B. Polyester: 0.1 µf ±20%, 50 VDCW.	
	C148	5494481P105	Ceramic disc: 330 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.	Q101*
	C149	5496267P10	Tantalum: 22 µf ±20%, 15 VDCW; sim to Sprague Type 150D.	
	C150	5496267P14	Tantalum: 15 µf ±20%, 20 VDCW; sim to Sprague	Q102 thru
	C151	5494481P105	Type 150D. Ceramic disc; 330 pf ±20%, 1000 VDCW; sim to	Q106 Q107*
	C152 thru	19A116080P1	RMC Type JF Discap. Polyester: 0.01 µf ±20%, 50 VDCm.	4107-
	C155	10411404501	Variable 200 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	Q108
l	C156*	19A116867P1	Variable, ceramic: 2.5-6 pf, +50% -10%, 160 VDCw; sim to 7-S-TRIKO-02. Added by REV B.	Q109*
	C157* thru C163*	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCh. Added by REV C	
	CR101	19A115250P1	DIODES AND RECTIFIERS Silicon, fast recovery, 225 ma, 50 PIV.	
	thru CR106	LUNITUZUUFI	222201, 200 2007(24), 220 mm, 00 417.	
	CV101 thru	5495769P12	Silicon, capacitive.	R101
١	CV103		MANYS AND DESCRIPTIONS	R102*
	J101	19A130924G1	Connector, receptacles; sim to Cinch 14H11613.	
				R103
•	1			R104

SYMBOL	GE PART NO.	DESCRIPTION
J103	198219374G1	Connector, Includes;
	19All6G51P1	Contact, electrical: sim to Malco XO-2
T101TT	19D416635G9	Coil.
L101F	19D416635G17	Coil.
L101M	19D416635G1	Coil.
TTOTH	19D416635G18	Coil.
L102LL	19D4 16635G9	Coil.
L102L	19D416635G17	Coil.
L102M L102H	19D416635G1	Coil.
L103LL	19D416635G18 19D416635G9	Coil.
L103L	19D416635G17	Coil.
L103M	19D416635G1	Coil,
L103H	19D416635G18	Coil.
L1041L	19A700000P16	Choke, RF: 2.7 µh ±10%, 1.20 ohms DC re
L104L	19A700000P15	Choke, RF: 2.20 µh ±10%, 0.97 ohms DC
L104M*	19A700000P6	Choke, RF: 0.33 µh ±10%, 0.07 ohms DC
		In REV G & earlier:
	7488079P7	Choke, RF: 1.50 µh ±10%, 0.50 ohms DC is sim to Jeffers 4411-10K.
L104H	19A700000P14	Choke, RF: 1.5 µh ±10%, 0.485 ohms DC
L105LL	19A700000P12	Choke, RF: 1.0 µh ±10%, 0.29 ohms DC re
L105L	19A700000P10	Choke, RF: 0.68 µh ±10%, 0.15 ohms DC 1
1105M	19A700000P8	Choke, RF: 0.47 µh ±10%, 0.09 ohms DC r
L105H	19A700000P6	Choke, RF: 0.33 µh ±10%, 0.07 ohms DC r
L106 and L107	19A700000P23	Choke, RF: 10.0 µh ±10%, 0.605 ohms DC
£108	19A700000P14	Choke, RF: 1.50 µh ±10%, 0.48 ohms DC r
P902		Includes:
	19B219594P2	Contact strip: 8 pins.
	19B219594P3	Contact strip: 9 pins.
Q101*	19A115330P1	Silicon, NPN.
•		In REV C & earlier:
	19A115910P1	Silicon, NPN; sim to Type 2N3904.
Q102 thru	19A115330P1	Silicon, NPN.
Q106		
Q107*	19A115328P1	Silicon, NPN.
	10.1750000	Rarlier than REV A:
0108	19A115330P1 19A115328P1	Silicon, NPN.
Q108 Q109*	19A116868P1	Silicon, NPN. Silicon, NPN; sim to Type 2N4427.
,		In G1,G2,G5,G6 of REV F & earlier: In G3,G7 of REV H & earlier: In G4,G8 of REV G & earlier:
	19A115329P2	Silicon, NPN.
R101	19A700113P57	Composition: 560 ohms ±5%, 1/2 w.
R102*	19A700106P83	Composition: 6.8K ohms ±5%, 1/4 w.
		In REV C & earlier:
	3R77P393K	Composition: 39K ohms ±10%, 1/2 w.
R103	19A700113P55	Composition: 470 ohms ±5%, 1/2 w.
R104	19A700113P35	Composition: 68 ohms ±5%, 1/2 w.
		



I. IN TWO FREQUENCY EXCITERS (GROUPS 1-4)
C157 IS CLIPPED OUT FOR COMBINATIONS
WITH 2 TRANSMIT LOWS. DA JUMPERS ARE
TRESENT ON FREQUENCY SWITCHING LINES OF
OTHER SIX LOCK CIRCUITS.

2. IN EIGHT-FREQUENCY EXCITERS (GROUPS 5-8), CAPACITORS C157-C163 ARE CLIPPED OUT AS REQUIRED TO MEET THE CUSTOMER REQUIREMENTS FOR FREQUENCIES. EXAMPLE: IF CUSTOMER WANTS (COMS FOR F1, F2, F5, F7, THEN CAPACITORS C157, C160, AND C162 ARE CLIPPED OUT. C158, C159, C161, C163 ARE LEFT IN.

- 1				171	F 1
ļ	IDENTIFICATION	25-30MHZ	30-36MHZ	36-42 MHZ	42~50 MHZ
Ļ					
į.	CII2	. 680	680	1000	1000
Ĺ	C123	91	62	56	43
ļ	C124	1.5	1.0	1.0	0.82
ŀ	C125	٥١	62	56	43
Ļ	C126	1.8	1.8	1.2	1.2
1	C127	91	62	56	43
Ĺ	C 29	47	33	22	15
L	C130	0.47	0.36	0.33	0.27
L	C131	47	33	22	15
L	C134	13	9	12	7
-	C135	0.68	0.51	0.56	0.47
Ļ	C136	13	9	12	7
L	C137	0.51	0.51	0.39	0.39
ļ	C138	13	9	12	7
ļ.	C141	100	82	150	100
L	0142	100	82	82	75
_	L108	39	39	1.5	39
L	L104	2.7	2.2	.33	1.5
L	L105	1,0	0.68	0.47	0.33
	R143	100	100	15	82
L	R144	15	F5 .	10	10
_	R107	20K	15K	15 K	
	R122	20K	15K	15K	5K
L	R123	20K	15K	15K	15K
_					

VOLTAGE READINGS ARE TYPICAL READINGS MADE WITH THE TRANSMITTER KEYED, AND MEASURED WITH A 20,000 OHMS-PER-VOLT METER WITH REFERENCE TO A- AND NOT CHAPSIS GROUND.

AN RF CHOKE (25-50 MICROHENRYS) IS USED IN THE HOT METER LEAD TO AVOID DETUNING RF CIRCUITS.

SCHEMATIC DIAGRAM

25-50 MHz, EXCITER BOARD 19D416659G1-G8

14

F4

F5

F6

F8

11 ←

14 -

17

Issue 6

OSCILLATOR MODULE

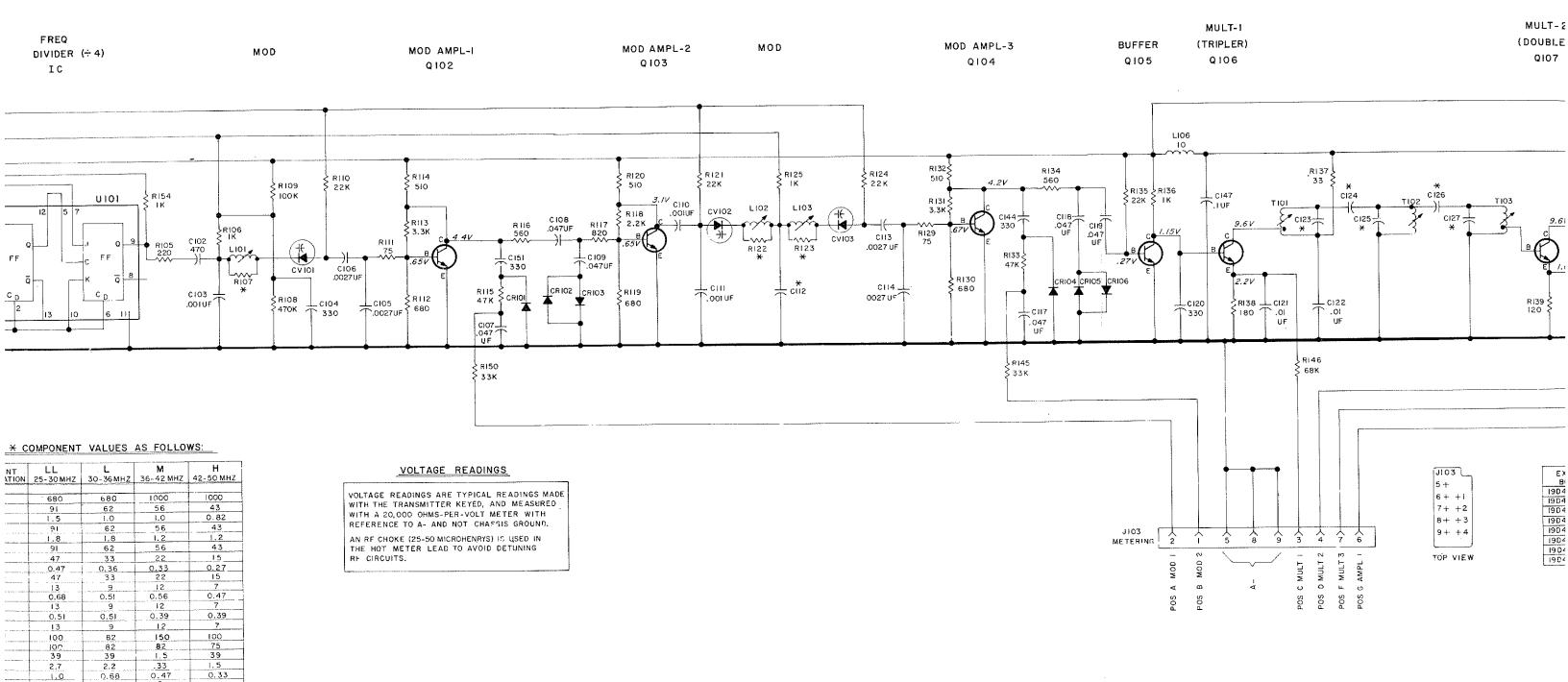
Y105 1XY105

XY106

Y107

YIO8

(19R621827, Rev. 20)



0.47

10 15 K

15K

15K

82 10

15K

15 K

15K

0.68

15K

15K

15K

1.0

20K 20K

20K

MULT-I MULT-2 MULT-3 (DOUBLER) AMPL-I BUFFER (TRIPLER) (DOUBLER) MOD AMPL-3 Q109 Q107 Q108 Q104 Q105 Q106 L108 ₹L107 10 LI06 R143 R132 510 ₹ RI40 22 R134 ± c141 560 C139 ŽLÍÒ4 4.2V 22 R135 R136 JUF C130 CI24 R131 \$ 3.3K ₹ C143 C146 C123 CII9 047 UF 5-60 ^√ 129 75 .047 UF RI52 .10 RI33 47K S .83V CRIO4 CRIO5 CRIO6 ∑LI05' ₹R130 \$680 **士ciaz** C120 RI38 CI2I .0I UF CI22 OI UF C145-_CI32 - .OI UF CI33 C128 .01 .07 R141 68 RI39 ≷ .047 UF R149 R|46 RI47 R148 R145 **∮**33κ § з́зк ≶33K \$33K } 68к ALL RESISTORS ARE 1/2 WATT UNLESS OTHERWISE SPECIFIED AND RESISTOR VALUES IN OHMS UNLESS FOLLOWED BY K-1000 OHMS - PICOFARADS (EQUAL TO MICROMICROFARADS). UNLESS FOLLOWED BY UF-8 MICROFARADS. INDUCTANCE VALUES IN MICROFARADS. INDUCTANCE VALUES IN MICROFARADS. INDUCTANCE VALUES MH-8 MILLIHENRYS OR H-8 HENRYS. J103 FREQ RANGE NO. FREQ EXCITER BOARD 19041665961 25-30 30-36 6++1 19041665962 7+ +2

19D416659G3

19D416659G4

19D416659G

19041665966 19D416659G

19041665938

8+ +3

9+ +4

TOP VIEW

D MULT 2 POS F MULT 3

POS

J103

METERING

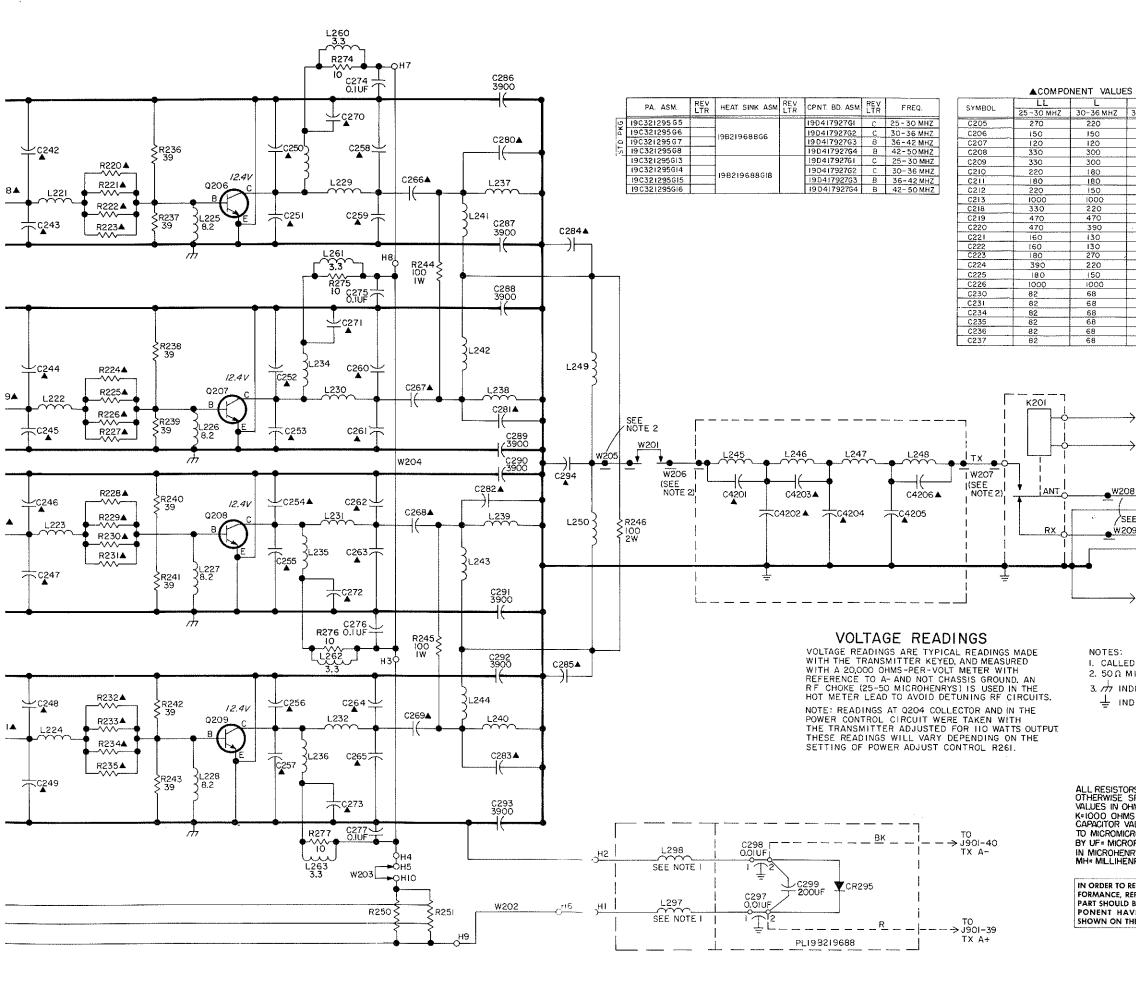
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36-42 42-50

25-30 30-36

IN ORDER TO RETAIN RATED EQUIPMENT PER-FORMANCE, REPLACEMENT OF ANY SERVICE PART SHOULD BE MADE ONLY WITH A COM-PONENT HAVING THE SPECIFICATIONS SHOWN ON THE PARTS LIST FOR THAT PART.

→ 1101



- M	H	57110	LL_	L	Г
-42 MHZ	42-50 MHZ	STMB	25-30 MHZ	30-36 MHZ	
100	100				-

30-36 MHZ 36-

200

120

220 180 180

180

150

120

180

120

. 47

→ J206 TO J9IO ON SYSTEM

SEE NOTE 2

<u>₩209</u>

NOTES:

→J207 BOARD (W904)

SHIELD OF W904

I. CALLED FOR ON PLI9C321295 2. 50 \(\Omega \) MICROSTRIP, W205-W209

ALL RESISTORS ARE 1/2 WATT UNLESS OTHERWISE SPECIFIED AND RESISTOR VALUES IN OHMS UNLESS FOLLOWED BY K=1000 OHMS OR MEG = 1,000,000 OHMS CAPACITOR VALUES IN PICOFARADS (EQUAL

IN ORDER TO RETAIN RATED EQUIPMENT PER-FORMANCE, REPLACEMENT OF ANY SERVICE

PART SHOULD BE MADE ONLY WITH A COM-

PONENT HAVING THE SPECIFICATIONS

SHOWN ON THE PARTS LIST FOR THAT PART.

TO MICROMICROFARADS) UNLESS FOLLOWED BY UF= MICROFARADS, INDUCTANCE VALUES IN MICROHENRYS UNLESS FOLLOWED BY MH= MILLIHENRYS OR H= HENRYS.

₹ INDICATES VEHICLE GROUND

3. الله INDICATES A-

< J203

→ TO ANT

√ J202

___ TO RX

220

300

150

220

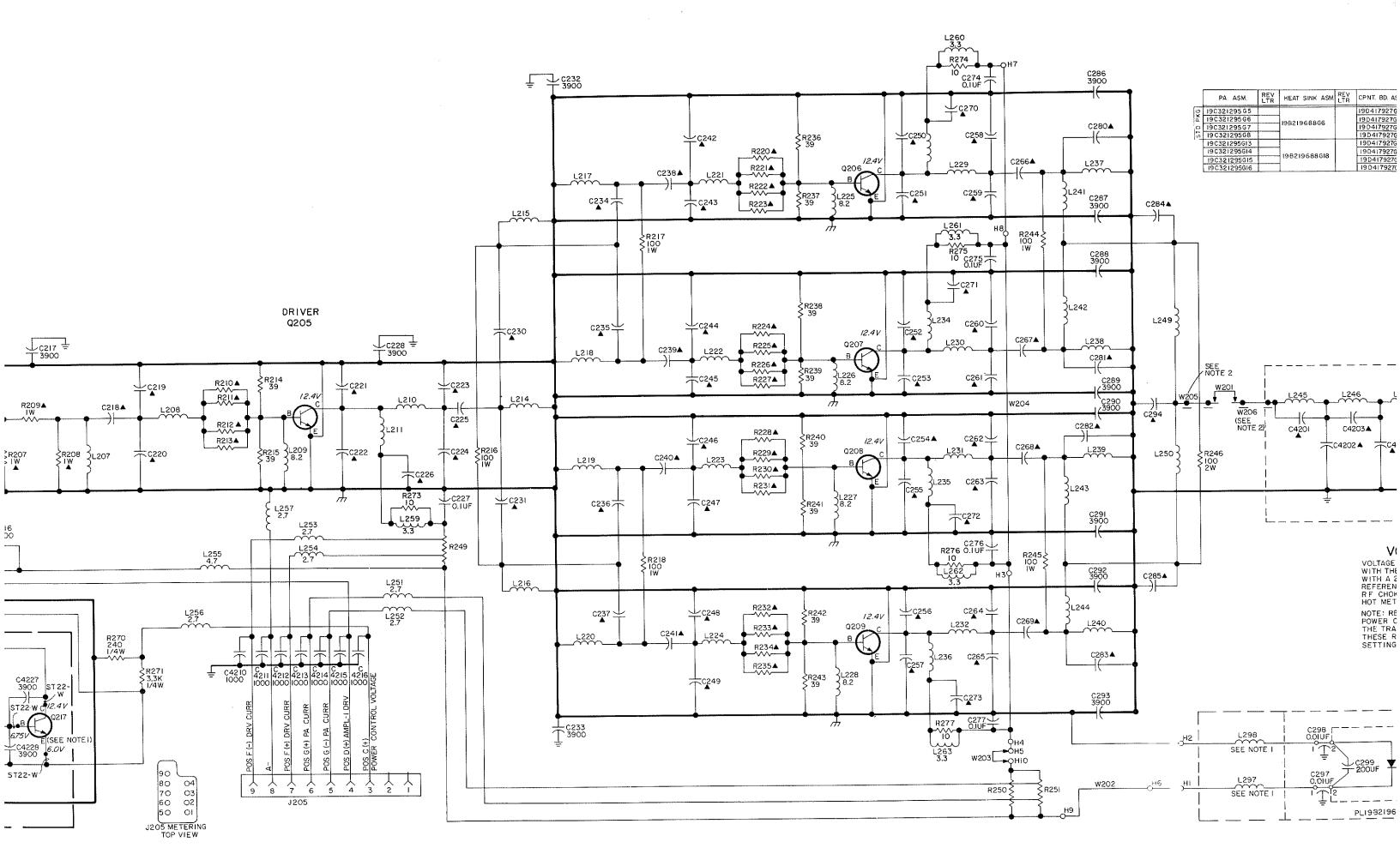
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PRO-100474-1-1-1-1	A COIVIE	ONE IT THE	UE3	
CVIIDO	LL	L	М	Н
SYMBOL	25-30 MHZ	30-36 MHZ	36-42 MHZ	42-50 MHZ
C238	TT-7-44			
***************************************	330	220	180	180
C239	330	220	180	180
C240	330	550	180	180
C241	330	220	180	180
C242	470	470		390
C243	470		390	
		390	330	330
C244	470	470	390	390
C245	470	390	330	330
C246	470	470	390	390
C247	470	390	330	
C248	470			330
		470	390	390
C249	470	390	330	330
C250	160	130	011	91
C251	160	130	110	91
C252	160	130	110	91
C253	160			
		130	110	91
C254	160	130	110	91
C255	160	130	110	91
C256	160	130	110	91
C257	160	130		
			110	91
C258	390	270	270	180
C259	180	550	120	180
C260	390	270	270	180
C261	180	220	120	180
C262	390	270		
			270	180
C263	081	220	120	180
C264	390	270	270	180
C265	180	220	120	180
C266	180	180	120	120
C267	180			
		180	120	120
C268	180	IBO	120	120
C269	180	180	120	120
C270	1000	1000	680	680
C271 ·	1000	1000	680	680
C272	1000			
		1000	680	680
C273	1000	1000	680	680
C280	82	68	56	47
C281	82	68	56	47
C282	82	68	56	47
C283	82			
		68	56	47
C284	240	200	160	140
C285	240	200	160	140
C294	160	130	110	91
C420I	91	68	56	51
C4202				
	110	91	68	. 56
04203	15	13	12	10
C4204	140	110	91	82
C4205	120	91	82	75
C4206	91	68	56	51
R203	12	10	8.2	4.7
R204	12	10	6.2	4.7
R207	680	680	680	910
R208	680	680	680	910
R209	8.2	8.2		
			8.2	5.6
R210	6.8	3.9	2.0	1.2
R2H	6.8	3.9	2.0	1.2
R212	6.8	3.9	2.0	1.2
R213	6.8	3.9	2.0	1.2
R220	6.8	3,9	2,0	1.2
R221				
	6.8	3,9	2.0	1.2
R222	6.8	3,9	2.0	1.2
R223	6.8	3.9	2.0	1.2
R224	6.8	3.9	2.0	1.2
R225	6.8	3.9	2.0	1.2
R226	6.8			
		3.9	2.0	1.2
R227	6.8	3.9	2.0	1,2
R228	6.8	3.9	2.0	1.2
R229	6.8	3.9	2.0	1.2
R230	6.8	3.9	2.0	1.2
R231	6.8	3.9	2.0	1.2
R232	6.8	3.9	2.0	1,2
R233	6.8	3.9	2.0	1.2
R234	6.B	3.9	. 2.0	1.2
R235	6.8	3.9	2.0	1.2
	1 0.0	U.J	E.V .	1.6

▲COMPONENT VALUES

SCHEMATIC DIAGRAM

25-50 MHz, 100-WATT POWER AMPLIFIER



CCT5-11

PARTS LIST

LB14899F

25-50 MHz, 100 WATT POWER AMPLIFIER 19C321295G5-G8 19C321295G13-G16

SYMBOL	GE PART NO.	DESCRIPTION
		. 19C321295G5, G13 25-30 MHz (LL) 19C321295G6, G14 30-36 MHz (L) 19C321295G7, G15 36-42 MHz (M) 19C321295G8, G16 42-50 MHz (H)
	10001000701	
L297 L298	19B219997P1 19B219997P2	Coil.
		TDANGISTONE
Q204	19A116965Pl	Silicon, NPN.
Q205 thru Q209	19A134104P1	Silicon, NPN.
Q217	19A116742P1	Silicon, NPN.
RT201	19A129379G1	Thermistor: 40K ohms ±20%, color code white; sim to Carborundum Type M0806J-5.
		POWER AMPLIFIER BOARD 19D417927G1 25-30 MHz (LL) 19D417927G2 30-36 MHz (L) 19D417927G3 36-42 MHz (M) 19D417927G4 42-50 MHz (H)
C201	19A116655P23	
thru C204	ISATIOUSOFES	RMC Type JF Discap.
C205LL	19A700105P46	Mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C205L	19A700105P44	Mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C205M and C205H	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C206L4	19A700105P38	Mica: 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C206L	19A700105P38	Mica: 150 pf ±5%, 500 YDCW; sim to Electro Motive Type DM-15.
C206M	19A700105P38	Mica: 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C206H	19A700105P44	Mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C207LL and C207L	19A700105£36	Mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C207₩	19A700105P38	Mica: 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C207H	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C208LL	19A116656P330J15	and the same and the same and
C208L	19A116658P300J15	
C208M	19A116656P200J4	Ceramic disc: 200 pf ±5%, 500 VDCH, temp coef -470 PPM.
C208H	19All6656Pl80J4	Ceramic disc: 180 pf ±5%, 500 VDCm, temp coef -470 PPM.
C209LL	19A116656P330J15	and we star \$500 MDCV town good

SYMBOL	GE PART NO.	DESCRIPTION
C209M	19A116556P200J4	Ceramic disc: 200 pf ±5%, 500 VDCb, temp coef
С209Н	19A118656P180J4	Ceramic disc: 180 pf ±5%, 500 VDCw, temp coef 470 PPM.
C310TT	19A700105£44	Mica: 220 pf £5%, 500 VDCW; sim to Electro Motive Type DM-15.
C210L	19A700105P41	Mica: 180 pf ±5%, 500 VDCm; sim to Electro Motive Type DM-15.
C210M and C210H	19A700105P38	Mica: 150 pf $\pm 5\%$, 500 VDCh; sim to Electro Motive Type DM-15.
C211LL and C211L	19A700105P41	Mica: 180 pf $\pm 5\%$, 500 VDCh; sim to Electro Motive Type DM-15.
C211M	19A700105P36	Mica: 120 pf ±5½, 500 VDCW; sim to Electro Motive Type DM-15.
C211H	19A700105P34	Mica: 100 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
C315FF	19A700105P44	Mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C212L	19A700105P38	Mica: 150 pf ±5%, 500 VDCm; sim to Electro Motive Type DM-15.
C212M and C212H	19A700105 P 36	Mica: 120 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
C213LL and C213L	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCw; sim to RMC Type JF Discap.
C213M and C213H	19A116655P17	Ceramic disc: 680 pf ±20%, 1000 VDCW; sim to RMC Type JF biscap.
C214	19A116966P107	Metallized polyester: 0.1 μf ±10%, 50 VDCW.
C216 and	19A116d55P23	Ceramic disc: 3900 pf t20%, 1000 VDCm; sim to RMC Type JF Discap.
C217 C218LL	7489162P39	Silver mica: 330 pf ±5%, 500 VDCW; sim to
C218L	19A700105P44	Electro Motive Type DM-15. Mica: 220 pf ±5%, 500 VDCw; sim to Electro
C218M and	19A700105P41	Motive Type DM-15. Mica: 180 pf ±5%, 500 YDCh; sim to Electro Motive Type DM-15.
C218H	7489162P43	Silver mica; 470 pf ±5%, 300 VDCm; sim to Electro Motive Type DM-15.
C219L	7489162943	Silver mica: 470 pf ±5%, 300 VDCW; sim to Electro Motive Type DM-15.
C219M	7489162.43	Silver mica: 470 pf ±5%, 300 VDCh; sim to Electro Motive Type DM-15.
C219H	7489162141	Silver mica: 390 pf ±5%, 500 VDCw; sim to Electro Motive Type DM-15.
C22014L	7489162P43	Silver mica: 470 pf ±5%, 300 VDCW; sim to Electro Motive Type DM-15.
C220L	7489162P41	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C220M	7489162P41	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
C220H	7489162P41	Silver mica: 390 pf ±5%, 500 YDCW; sim to Electro Motive Type DM-15.
C22114L	19A116656P160J3	Ceramic disc: 180 of ±5%, 500 VDCH, temp coef -330 PPM.
C221L	19A116656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCh, temp coef -150 PPM.
C221M	19A116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM.
C221H	19A116656P9lJ0	Ceramic disc: 91 pf ±5%, 500 VDCh, temp coef O PPM.
C22211	19A116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCm, temp coef -330 PPM.
C222L	19All6856P130J1	Ceramic disc: 130 pf ±5%, 500 VDCw, temp coef -150 PPM.
C222M	19A116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCm, temp coef -80 PPM.
C222H	19Al16656P91J0	Coramic disc: 91 pf ±5%, 500 VDCw, temp coef 0 PPM.

SYMBOL	GE PART NO.	DESCRIPTION
C22314L	19A700105141	Mica: 180 pf ±5%, 500 VDC%; sim to Electro Motive Type DM-15.
C223L and C223M	19A700105P46	Mica: 270 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
C223H	19A700105P41	Mica: 180 pf ±5%, 500 VDCm; sim to Electro Motive Type DM-15.
C2241L	7489162P41	Silver mica: 180 pf ±5%, 500 VDCm; sim to Electro Motive Type DM-15.
C224L	19A700105P44	Mica: 220 pf ±5%, 500 VDC%; sim to Electro Motive Type DM~15.
C224 M	19A700105P36	Mica: 120 pf ±5%, 500 VDCw; sim to Electro Motive Type DM-15.
C224H	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
C22514L	19A700105P41	Mica: 180 pf ±5%, 500 VDC%; sim to Electro Motive Type DM-15.
C225L	19A700105P38	Mica: 150 pf ±5%, 500 VDCw; sim to Electro Motive Type DM-15.
C225M and C225H	19A700105P36	Mica: 120 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
C226LL and C226L	19al16355P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C226M and C226H	19A116655P17	Ceramic disc: 680 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.
C227	19a116966P107	Metallized polyester: 0.1 µf ±10%, 50 VDCW.
C228	19A116355P23	Ceramic disc: 3900 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.
C229	5496267P13	Tantalum: 2.2 μ f $\pm 20\%$, 20 VDCm; sim to Sprague Type 150D.
C230LL	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef 0 PPM.
C230L	19A116656P6840	Ceramic disc: 68 pf ±5%, 500 VDCm, temp coef 0 PPM.
C230M	19A116656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef 0 PPM.
C230H	19A11G356P47J0	Ceramic disc: 47 pf ±5%, 500 VDCw, temp coef O PPM.
C2311.L	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef
C231L	19A116056P68J0	Ceramic disc: 68 pf ±5%, 500 VDCb, temp coef 0 PPM.
C231M	19All6656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCh, temp coef 0 PPM.
C231H	19A116656P47J0	Ceramic disc: 47 pf ±5%, 500 VDCh, temp coef
C232 and	19A116655P23	Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C2341L	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCw, temp coef
C234L	19A116656P68J0	O PPM. Ceramic disc: 68 pf ±5%, 500 VDCm, temp coef
C234M	19A116656P56J0	O PPM. Ceramic disc: 56 pf ±5%, 500 VDCm, temp coet
C234H	19A116656P47J0	O PPM. Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef
C235LL	19A116656P82J0	O PPM. Ceramic disc: 82 pf ±5%, 500 VDCh, temp coef
C235L	19A116356P68J0	O PPM. Ceramic disc: 68 pf ±5%, 500 VDCH, temp coef
C235M	19A116656P56J0	O PPM. Ceramic disc: 56 pf ±5%, 500 YDCW, temp coef
C235H	19A116656P47J0	O PPM. Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef
C236LL	19A116656P82J0	O PPM. Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef
C236L	19A116656P68J0	O PPM. Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef
C236M	19A116656P56J0	O PPM. Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef
	1	O PPM. Ceramic disc: 47 pf ±5%, 500 VDCm, temp coef

	SYMBOL	GE PART NO.	DESCRIPTION
	C237LL	19A116856P82J0	Ceramic disc: 82 pf ±5%, 500 VDCH, temp of PPM.
	C237L	19A116356P68J0	Ceramic disc: 68 pf ±5%, 500 VDCh, temp (
	C237M	19A116656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCk, temp of PPM.
	С237И	19A116d56P47J0	Ceramic disc: 47 pf ±5%, 500 VDCW, temp of
ro	C238LL	7489162P39	Silver mica: 330 pf ±5%, 500 VDCw; sim to
:	C238L	19A700105P44	Electro Motive Type DM-15. Mica: 220 pf ±5%, 500 YDCm; sim to Electronic Type DM-15.
	C238M and	19A700105P41	Mica: 180 pf ±5%, 500 VDCw; sim to Electronic Type DM-15.
	C238H C239LL	7489162P39	Silver mica: 330 pf ±5%, 500 VDCW; sim to
	C239L	19A700105P44	Electro Motive Type DM-15. Mica: 220 pf ±5%, 500 VDCW; sim to Electron DM-15.
	C239M and C239H	19A700105P41	Type DM-15. Mica: 180 pf ±5%, 500 VDCh; sim to Electrope DM-15.
	C24011	7489162239	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
	C240L	19A700105P44	Mica: 220 pf ±5%, 500 VDCW; sim to Electronic Motive Type DM-15.
	C240M and C240H	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electr Motive Type DM-15.
	C241LL	7489162P39	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
	C241L	19A700105P14	Mica: 220 pf ±5%, 500 VDCW; sim to Elect: Type DM-15.
1	C241M and C241H	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electr Type DM-15.
	C24214. and C242L	7489162P43	Silver mica: 470 pf ±5%, 300 VDCN; sim to Electro Motive Type DM-15.
	C242M and C242H	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.
	C243LL	7489162943	Silver mica: 470 pf ±5%, 300 VDCW; sim to Electro Motive Type DM-15.
	C243L	7489162P41	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.
:	C243M and C243H	7489162P39	Silver mica: 330 pf ±5%, 500 VDCh; sim t Electro Motive Type DM-15.
	C244LL and C244L	7489162P43	Silver mica: 470 pf ±5%, 300 VDCH; sim t Electro Motive Type DM-15.
	C244M and C244H	7489162P41	Silver mica: 390 pf ±5%, 500 VDCW; sim t Electro Motive Type DM-15.
	C245LL	7489162P43	Silver mica: 470 pf ±5%, 300 VDCW; sim t Electro Motive Type DM-15.
	C245L	7489162P41	Silver mica: 390 pf ±5%, 500 VDCN; sim t Electro Motive Type DM-15.
1.	C245M and C245H	7489162P39	Silver mica; 330 pf ±5%, 500 VDCW; sim t Electro Motive Type DM-15.
	C246LL and C246L	7489162P43	Silver mica: 470 pf ±5%, 300 VDCh; sim t Electro Motive Type DM-15.
	C246M and C246H	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim t Electro Motive Type DM-15.
	C2471.L	7489162P43	Silver mica; 470 pf ±5%, 300 VDCW; sim t Electro Motive Type DM-15.
	C247L	7489162P41	Silver mica: 390 pf ±5%, 500 VDCw; sim t Electro Motive Type DM-15.
	C247M and C247H	7489162P39	Silver mica: 330 pf ±5%, 500 VDCW; sim 1 Electro Motive Type DM-15.
	C248LL and C248L	7489162P43	Silver mica: 470 pf ±5%, 300 VDCW; sim 1 Electro Motive Type DM-15.

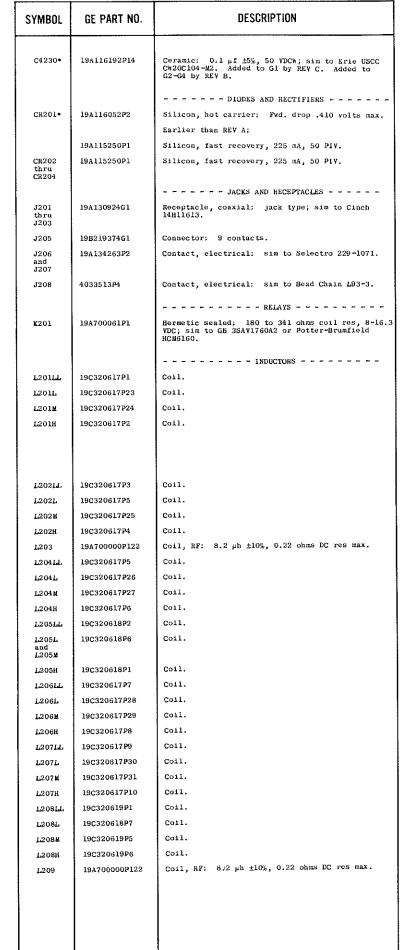
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DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	
Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	С237ы.	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCh, temp coef 0 PPM.	C248M and C248H	7489162F41	Silver mica: 390 pf 15%, 500 VDCh; sim to Electro Motive Type DM-15.	C258LL.	7489162P41	Silver mica: 390 pf ±5%, 500 VDC%; sim to Electro Motive Type DM-15.	C269M and	19A700105236	Mica: 120 pr
Mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C237L	19A116656P68J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.	C249LL	7489162P43	Silver mica: 470 pf ±5%, 300 VDCk; sim to Electro Motive Type DM-15.	C258L and C258M	19A700105P46	Mica: 270 pf ±5%, 500 VDCh; sim to Electro Motive Type DN-15.	C269H C270LL and	19A116355P19	Ceramic disc:
Mica: 180 pf ±5%, 500 VDCn; sim to Electro Motive Type DM-15.	C237M	19A116656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCw, temp coef O PPN.	C249L	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C258H and	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	270L C270M	19A116655P17	sim to RMC Ty Ceramic disc:
Silver mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C237H	19A116656P47J0	Ceramic disc; 47 pf ±5%, 500 VDCh, temp coef 0 PPM.	C249M and	7489162P39	Silver mica: 330 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C258LL C259L	19A700105P44	Mica: 220 pf ±5%, 500 VDCW; sim to Electro	and C270H		sim to RMC Ty
Mica: 220 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-13.	C238LL C238L	7489162P39 19A700105P44	Silver mica; 330 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15. Mica: 220 pf ±5%, 500 VDCh; sim to Electro	С249H С250£.L	19A116656P160J3	Ceramic disc: 160 pf ±5%, 500 YDCH, temp coef -330 PPM.	C259M	19A700105P36	Motive Type DM-15. Mica: 120 pf ±5%, 500 YDCm; sim to Electro Motive Type DM-15.	C271LL and C271L	19A116655P19	Ceramic disc: sim to RMC Ty
Mica: 120 pf ±5%, 500 VDCm; sim to Electro Motive Type DM-15.	C238M	19A700105P41	Motive Type DM-15. Mica: 180 pf ±5%, 500 VDCh; sim to Electro	C250L	19A116656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef -150 PPM.	С259Н	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C271M and	19A116655P17	Ceramic disc; sim to RMC Ty
Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	and C238H		Motive Type DN-15.	C250M	19A116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM.	C260LL	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C271H C272LL and	19A116655P19	Ceramic disc:
Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C239LL	7489162P39 19A700105P44	Silver mica: 330 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	С250Н	19A116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM.	C260L and	19A700105P46	Mica: 270 pf ±5%, 500 YDCm; sim to Electro Motive Type DM-15.	C272L	19A116655P17	Ceramic disc:
Mica; 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DN-15.	C239L	19A700105P44	Mica: 220 pf ±5%, 500 VDCW; sim to Electro Type DM-15. Mica: 180 pf ±5%, 500 VDCW; sim to Electro	C251LL	19A116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef -330 PPM.	C260M C260H	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro	and C272H		sim to RMC Ty
Mica: 120 pf ±5%, 500 VDCh; sim to Electro Motive Type DN-15.	and C239H		Type DM-15.	C251L	19A116656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef -150 PPM.	and C26lLL C261L	19A700105P44	Motive Type DM-15. Mica: 220 pf ±5%, 500 VDCW; sim to Electro	C273LL and C273L	19A116655P19	Ceramic disc: sim to RMC Ty
Ceramic disc: 1000 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.	C240LL	7489162P39	Silver mica: 330 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C251M	19A116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM.	C261L C261M	19A700105P44	Motive Type DM-15. Mica: 120 pf ±5%, 500 VDCW; sim to Electro	C273M and C273H	19A116655P17	Ceramic disc: sim to RMC Ty
Ceramic disc: 680 pf ±20%, 1000 VDCm; sim to RMC Type JF Discap.	C240L	19A700105P44	Mica: 220 pf £5%, 500 VDCh; sim to Electro Motive Type DM-15.	C251H	19A116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM.	C261H	19A700105P41	Motive Type DM-15. Mica: 180 pf ±5%, 500 VDCW; sim to Electro	C273H C274 thru	19A116966P107	Metallized po
Metallized polyester: 0.1 \(\mu f \pm 10\% \), 50 VDCW.	C240M and C240H	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C252LL	19A116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCw, temp coef	C262LL	7489162P41	Motive Type DM-15. Silver mica: 390 pf ±5%, 500 VDCW; sim to	C277	19A11G656P82J0	Ceramic disc:
Ceramic disc: 3900 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.	C241LL	7489162P39	Silver mica: 330 pf ±5%, 500 VDCM; sim to Electro Motive Type DM-15.	C252L C252M	19A116656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef -150 PPM. Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef	C262L and	19A700105P46	Electro Motive Type DM-15. Mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C280L	19A116656P68J0	O PPM. Ceramic disc:
Tantalum: 2.2 µf ±20%, 20 VDCw; sim to Sprague Type 150D.	C241L	19A700105P44	Mica: 220 pf ±5%, 500 VDCb; sim to Electro Type DM-15.	C252H	19A116656P91J0	-80 PPM. Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef	262M C262H	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro	C280M	19A116656P56J0	0 PPM. Ceramic disc:
Ceramic disc: 82 pf ±5%, 500 VDCm, temp coef 0 PPM.	C241M and C241H	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Type DM-15.			0 РРМ.	and C263LL		Motive Type DM-15.	С280Н	19a116656P47J0	O PPM. Ceramic disc: O PPM.
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Ceramic disc: 68 pf ±5%, 500 VDCw, temp coef 0 PPM.	C24211	7489162P43	Silver mica: 470 pf ±5%, 300 VDCW; sim to Electro Motive Type DM-15.	C253LL	19A116856P160J3	Ceramic disc: 160 pf t5%, 500 VDCW, temp coef	C263L	19A700105P44	Mica: 220 pf ±5%, 500 VDCw; sim to Electro Motive Type DM-15.	C28111T	19A116656P82JO	Ceramic disc:
Ceramic disc; 56 pf ±5%, 500 VDCW, temp coef 0 PPM.	C242L	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to	C253L	19Al16656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCh, temp coef -150 PPM.	C263M	19A700105P36	Mica: 120 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C2811.	19A116656P68J0	O PPM. Ceramic disc:
Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef 0 PPM.	and C242H		Electro Motive Type DM-15.	C253M	19A116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM.	С263Н	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C281M	19A116656P56J0	O PPM. Ceramic disc: O PPM.
Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef 0 PPM.	C243LL	7489162P43	Silver mica: 470 pf ±5%, 300 VDCh; sim to Electro Motive Type DM-15.	С253Н	19A116656P91J0	Ceramic disc: 91 pf ±5%, 500 YDCw, temp coef 0 PPM.	C2641.L	7489162P41	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C281H	19A116656P47J0	Ceramic dise:
Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.	C243L	7489162P41 7489162P39	Silver mica: 390 pf ±5%, 500 YDCW; sim to Electro Motive Type DM-15. Silver mica: 330 pf ±5%, 500 YDCW; sim to	C254LL	19A116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCH, temp coef -330 PPM.	C264L and	19A700105P46	Mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C2821.1.	19A116656P82J0	Ceramic disc:
Ceramic disc: 56 pf ±5%, 500 VDCh, temp coef 0 PPM.	C243M and C243H		Electro Motive Type DM-15.	C254L	19A116056P130J1	Ceramic disc: 130 pf ±5%, 500 VDCh, temp coef -150 PPM.	C264M C264H and	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C282L	19A116656P68J0	Ceramic disc:
Ceramic disc: 47 pf ±5%, 500 YDCW, temp coef 0 PPM.	C244LL and C244L	7489162P43	Silver mica: 470 pf ±5%, 300 VDCH; sim to Electro Motive Type DM-15.	C254M	19A116656P110J8	-80 PPM.	265L C265L	19A700105P44	Mica: 220 pf ±5%, 500 VDCW; sim to Electro	C282M	19A116656P56J0	Ceramic disc: 0 PPM.
Ceramic disc: 3900 pf ±20%, 1000 VDC%; sim to RMC Type JF Discap.	C244M and	7489162P41	Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	С254Н	19A116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCw, temp coef 0 PPM.	C265¥	19A700105P36	Motive Type DM-15. Mica: 120 pf ±5%, 500 VDCW; sim to Electro	С282Н	19A116656P47J0	Ceramic disc: 0 PPM.
Ceramic disc: 82 pf ±5%, 500 VDCm, temp coef 0 PPM.	C244H C245LL	7489162P43	Silver mica; 470 pf ±5%, 300 VDCh; sim to flectro Motive Type DM-15.	C255LL	19A116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef -330 PPM. Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef	C265H	19A700105P41	Motive Type DM-15. Mica: 180 pf ±5%, 500 VDCW; sim to Electro	C283LL	19Al16656P82J0	Ceramic disc:
Ceramic disc: 68 pf ±5%, 500 VDCM, temp coef 0 PPM.	C245L	7489162P41	Electro Motive Type DM-15. Silver mica: 390 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C255L	19A116656P130J1 19A116656P110J8	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef -150 PPM. Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef	and C266LL	19A700105P41	Motive Type DM-15. Mica: 180 pf ±5%, 500 VDCW; sim to Electro	C283L	19A116656P68J0	Ceramic disc:
Ceramic disc: 56 pf ±5%, 500 VDCm, temp coef 0 PPM.	C245M and	7489162P39	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C255M C255H	19A116656P11038	-80 PPM. Ceramic disc: 91 pf ±5%, 500 VDCw, temp coef	C266L C266M	19A700105P41 19A700105P36	Mica: 180 pf 15%, 500 VDCW; sim to Electro Mica: 120 pf ±5%, 500 VDCW; sim to Electro	C283M	19A116356P56J0	Ceramic disc
Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef 0 PPM.	C245H C246LL	7489162P43	Silver mica; 470 pf ±5%, 300 VDCw; sim to	C256LL	19A116656P160J3	O PPM. Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef	and C266H		Motive Type DM-15.	C283H C284LL	19A116656P47J0	Ceramic disc: 0 PPM, Metallized to
Ceramic disc: 82 pf ±5%, 500 VDCh, temp coef 0 PPM.	and C246L		Electro Motive Type DM-15.	C256L	19A116656P130J1	-330 PPM. Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef	C267LL and C267L	19A700105P41	Mica: 180 pf ±5%, 500 VDCm; sim to Electro Motive Type DM-15.	C284LL C284L	19A700015P36	Metallized to
Ceramic disc: 68 pf ±5%, 500 VDCH, temp coef 0 PPM.	C246M and C246H	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C256M	19A116656P110J8	-150 PPM. Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef	C267M and	19A700105P36	Mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C284M C284H	19A700015P34 19A116679P140J	Metallized to
Ceramic disc: 56 pf ±5%, 500 VDCH, temp coef 0 PPM. Ceramic disc: 47 pf ±5%, 500 VDCH, temp coef	С247Ы.	7489162P43	Silver mica; 470 pf ±5%, 300 VDCW; sim to Electro Motive Type DM-15.	С256н	19A116656P91J0	-80 PPM. Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM.	C267H C268LL	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro	C285LL	19A700015P38	Metallized to
Ceramic disc: 47 pr ±5%, 500 vDCM, temp coef Ceramic disc: 82 pf ±5%, 500 vDCM, temp coef	C247L	7489162P41	Silver mica: 390 pf ±5%, 500 VDCm; sim to Electro Motive Type DM-15.	C257LL	19A116656P160J3		and C268L C268M	194700105027	Motive Type DM-15. Mica: 120 pf ±5%, 500 VDCW; sim to Electro	C285L C285M	19A700015P36 19A700015P34	Metallized t
O PPM. Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef	C247M and C247H	7489162P39	Silver mica: 330 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C257L	19A116656P13OJl	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef -150 PPM.	C268M and C268H	19A700105P36	Motive Type DM~15.	C285H	19A116679P140J	Mica: 140 p
O PPM. Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef	C248LL and	7489162P43	Silver mica: 470 pf ±5%, 300 VDCH; sim to Electro Motive Type DM-15.	С257М	19All6656Pll0J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM.	C269LL and C269L	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C286 thru C293	19A116655P23	RMC Type JF
O PPM. Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef	C248L			C257H	19A116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM.	.2004			C294LL C294L	19A700015P34 19A700015P32	Teflon/Mica: Teflon/Mica:
О РРМ.										GX84F	12 50013832	

GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to	C258LL	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to	C269M	19A700105 2 36	Mica: 120 pf ±5%, 500 VDCb; sim to Electro	C294M	19A700015P30	Metallized teflon: 110 pf ±5%, 250 VDCh.
489162P43	Electro Motive Type DM-15. Silver mica: 470 pf ±5%, 300 VDCW; sim to	C258L and	19A700105P46	Electro Motive Type DM-15. Mica: 270 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	and C269H C270LL	19A116355P19	Motive Type DM-15. Ceramic dusc: 1000 pf ±20%, 1000 VDCh;	C294H C4201LL*	19A700015P28 19A116656P91J2	Metallized teflon: 91 pf ±5%, 250 VDCm. Ceramic disc: 91 pf ±5%, 500 VDCm, temp coef
189162P41	Electro Motive Type DM-15. Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C258M C258H and	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15,	and C270L		sim to RMC Type JF Discap.			-220 PPM. In REV A & earlier:
89162P39	Silver mica: 330 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C258LL C259L	19A700105P44	Mica: 220 pf ±5%, 500 VDCW; sim to Electro	C270M and C270H	19A116655P17	Ceramic disc: 680 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.		19A116656P82J1	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef ~150 PPM.
A116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef	C259M	19A700105P36	Motive Type DM-15. Mica: 120 pf ±5%, 500 VDCh; sim to Electro	C271LL and C271L	19A116655719	Coramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	C4201L	19A116656P68J1	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef -150 PPM.
All6656P130Jl	-330 PPM. Ceramic disc: 130 pf ±5%, 500 VDCH, temp coef -150 PPM.	С259Н	19A700105P41	Motive Type DM-15. Mica: 180 pf ±5%, 500 VDCm; sim to Electro Motive Type DM-15.	C271M and	19A116655P17	Ceramic disc: 680 pf ±20%, 1000 VDCb; sim to RMC Type JF Discap.	C4201M	19A116656P56J1 19A116656P51J1	Ceramic disc: 56 pf ±5%, 500 VDCh, temp coef -150 PPM. Ceramic disc: 51 pf ±5%, 500 VDCh, temp coef
116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM.	C260LL	7489162P41	Silver mica; 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C271H C272LL and	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	C4202LL	19A700015P30	-150 PPM. Metallized teflon: 110 pf ±5%, 250 VDCW.
All6656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM.	C260L and	19A700105P46	Mica: 270 pf ±5%, 500 YDCh; sim to Electro Motive Type DM-15.	C272L	19A116655P17	Ceramic disc: 680 pf ±20%, 1000 VDCm;	C4202L	19A700015P28	Metallized teflon: 91 pf ±5%, 250 VDCW. Metallized teflon: 68 pf ±5%, 250 VDCW.
116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef -330 РРМ.	C260M C260H and	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	and C272H		sim to RMC Type JF Discap.	C4202M C4202H	19A700015P23	Metallized teflon: 56 pf ±5%, 250 VDC%.
116656Pl30Jl	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef -150 PPM.	C261LL C261L	19A700105P44	Mica: 220 pf ±5%, 500 VDC%; sim to Electro	C273LL and C273L	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	C4203LL	19A116656P15J1	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef -150 PPM.
A116856P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM.	C261M	19A700105P36	Motive Type DM-15. Mica: 120 pf ±5%, 500 YDCW; sim to Electro	C273M and C273H	19A116655P17	Ceramic disc: 680 pf ±20%, 1000 VDCw; sim to RMC Type JF Discap.	C4203L	19A116656P13J1	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -150 PPM.
116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM.	C261H	19A700105P41	Motive Type DN-15. Mica: 180 pf ±5%, 500 VDCW; sim to Electro	C274 thru	19All6966P107	Metallized polyester: 0.1 μf ±10%, 50 VDCW.	C4203M	19A116656P12J1	Ceramic disc: 12 pf ±5%, 500 VDCH, temp coef ~150 PPM Ceramic disc: 10 pf ±5%, 500 VDCH, temp coef
116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCm, temp coef -330 PPM. Ceramic disc: 130 pf ±5%, 500 VDCm, temp coef	C262LL	7489162P41	Motive Type DM-15. Silver mica: 390 pf ±5%, 500 VDCH; sim to Electro Motive Type DM-15.	C277 C280LL	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCm, temp coef	C4203H C4204LL	19A116656P10J1 19A116679P140J	-150 PPM. Mica: 140 pf ±5%, 250 VDCW.
.116656P110J8	-150 PPM. Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef	C262L and	19A700105P46	Mica: 270 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C280L	19A116656P68J0	O PPM. Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef O PPM.	C4204L	19A700015P30	Metallized teflon: 110 pf ±5%, 250 VDCW.
116656P91J0	-80 PPM. Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef	C262M C262H	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro	C280M	19A116656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCw, temp coef 0 PPM.	C4204M C4204H	19A700015P28 19A700015P27	Metallized teflon: 91 pf ±5%, 250 VDCW. Metallized teflon: 82 pf ±5%, 250 VDCW.
	O PPM.	and C263LL		Motive Type DM-15.	C280H	19A116356P47J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.			
1116856P160J3	Ceramic disc; 160 pf t5%, 500 VDCH, temp coef -330 PPM.	C263L	19A700105P44	Mica: 220 pf t5%, 500 VDCm; sim to Electro Motive Type DM-15.	C381FT	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCh, temp coef O PPM.	C4205LL*	19A700015P31	Metallized teflon: 120 pf ±5%, 250 VDCW.
116656P130J1	Coramic disc: 130 pf ±5%, 500 VDCh, temp coef ~150 PPM.	C263M	19A700105P36	Mica: 120 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C281L	19A116656P68J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.		19A116656P82J1	In REV A & earlier: Ceramic disc: 82 pf ±5%, 500 VDCw, temp coef
116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM.	C263H	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C281M	19All6656P56J0	Ceramic disc: 56 pf ±5%, 500 VDCw, temp coef 0 PPM.	C4205L*	19A700015P28	-150 PPM. Metallized teflon: 91 pf ±5%, 250 VDCW.
116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCm, temp coef 0 PPM.	C264LL	7489162P41	Silver mica: 390 pf ±5%, 500 VDCh; sim to Electro Motive Type DM-15.	C281H	19All6656P47J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.		19A116679P100J	lu REV B & earlier: Mica: 100 pf ±5%, 250 VDCW.
116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef -330 PPM.	C264L and C264M	19A700105P46	Mica: 270 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C282LL	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef 0 PPM.	C4205M	19A700015P27	Metallized teflon: 82 pf ±5%, 250 VDCW.
116656P130J1	Ceramic disc: 130 pf ±5%, 500 VDCw, temp coef -150 PPM.	C264H	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C282L	19A116656P68J0	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef 0 PPM.	C4205H C4206LL*	19A700015P26 19A116656P91J2	Metallized teflon: 75 pf ±5%, 250 VDCW. Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef
116656P110J8	Ceramic disc; 110 pf ±5%, 500 VDCh, temp coef -80 PPM.	C265LL C265L	19A700105P4·4	Mica: 220 pf ±5%, 500 VDCW; sim to Electro	C282M	19A116656P56J0	Ceramic disc; 56 pf ±5%, 500 VDCW, temp coef 0 PPM.			-220 PPM. In REV A & earlier:
1116656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM. Coramic disc: 160 pf ±5%, 500 VDCW, temp coef	C265M	19A700105P36	Motive Type DM-15. Mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C282H	19A116656P47J0	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef O PPM.		19A116656P82J1	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef -150 PPM.
1116656P160J3 1116656P130J1	-330 PPM. Ceramic disc: 130 pf ±5%, 500 VDCH, temp coef	C265H and	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C283LL	19A116656P82J0	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef 0 PPM. Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef	C4206L	19A116656P68J1	Ceramic disc: 68 pf ±5%, 500 VDCH, temp coef -150 PPM.
Al16656Pll0J8	-150 PPM. Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef	C266TT	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro	C283L	19A116656P56J0	O PPM. Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef	C4206M	19A116656P56J1	Ceramic disc: 56 pf ±5%, 500 VDCw, temp coef -150 PPM.
1116656P91J0	-80 PPM. Ceramic disc: 91 pf ±5%, 500 VDCm, temp coef	C266M	19A700105P36	Mica: 120 pf ±5%, 500 VDCW; sim to Electro	С283н	19A116356P47J0	O PPM. Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef	С4206Н	19A116656P51J1	Ceramic disc: 51 pf ±5%, 500 VDCW, temp coef -150 PPM. Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim t
Al16856Pl60J3	O PPM. Ceramic disc: 160 pf ±5%, 500 VDCh, temp coef -330 PPM.	and C266H	104700105711	Motive Type DM-15. Mica: 180 pf ±5%, 500 VDCW; sim to Electro	C284LL	19A700015P38	0 PPM. Metallized teflon: 240 pf ±5%, 250 VDCW.	C4210 thru C4216	19A116655P19	RMC Type JF Discap.
All6656P130Jl	Ceramic disc: 130 pf ±5%, 500 VDCW, temp coef -150 PPM.	C267LL and C267L	19A700105P41	Motive Type DM-15.	C284L	19A700015P36	Metallized teflon: 200 pf ±5%, 250 VDCw. Metallized teflon: 160 pf ±5%, 250 VDCw.	C4220	19Al16655P23	Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim t RMC Type JF Discap.
.116656P110J8	Ceramic disc: 110 pf ±5%, 500 VDCH, temp coef -80 PPM.	C267M and C267H	19A700105P36	Mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C284M	19A700015P34 19A116679P140J	Mica: 140 pf ±5%, 250 VDCh.	C4221 and C4222	19A116655P17	Ceramic disc: 680 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
Al16656P91J0	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef 0 PPM.	C268LL and	19A700105P41	Mica: 180 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C285LL C285L	19A700015P38 19A700015P36	Metallized teflon: 240 pf ±5%, 250 VDCw. Metallized teflon: 200 pf ±5%, 250 VDCw.	C4223 thru	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim t RMC Type JF Discap.
A116656P160J3	Ceramic disc: 160 pf ±5%, 500 VDCW, temp coef -330 PPM.	C268L	19A700105₽36	Mica: 120 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	C285M	19A700015P34	Metallized teflon: 160 pf ±5%, 250 VDCW.	C4225 C4226	19A116655P23	Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim t RMC Type JF Discap.
Al16656P130J1	Ceramic disc: 130 pf ±5%, 500 VDC%, temp coef -150 PPM.	and C268H C269LL	19A700105P41	Mica: 180 pf ±5%, 500 VDCh; sim to Electro	C285H C286	19A116679P140J 19A116655P23	Mica: 140 pf ±5%, 250 VDCW. Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim to	thru C4228 C4229	19A116655P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim t
		بشباده عب	1 724,00103541	Motive Type DM-15.	thru	1	RMC Type JF Discap.	1 6-12-25		RMC Type JF Discap.
All6656Pll0J8	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM. Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef	and C269L		motive Type Dim 40.	C293 C294LL	19A700015P34	Teflon/Mica: 160 pf ±5%, 250 VDCm.			

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E PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
11/210DD14	Constitution of the State of th	L210LL	190320617P11	Coil,	1,225	19A700000P122	Coil, RF: 8.2 µh ±10%, 0.22 ohms DC res max.	L242LL	19C320617P41	Co11.
A116192P14	Ceramic: 0.1 µf ±5%, 50 VDCh; sim to Erie USCC Ch2OClO4-M2. Added to Gl by REV C. Added to G2-G4 by REV B.	L210L	19C320617P4	Coil.	thru L228		·	L242L	19C320617P42	Coil.
	dz-ox by hav b.	and L210M			L229LL	19C320617P16	Coil.	L242M	19C320617P43	Coil.
	DIQUES AND RECTIFIERS	£210H	19C32O617P12	Coil.	L229L	19C320617P35	Coil.	L242H	19C320617P44	Coil.
A116052P2	Silicon, hot carrier: Fwd, drop .410 volts max.	£211££	19C32O618P2	Coil.	1.229 M	19C32O617P12	Coil.	L243LL	19C320617P41	Coil.
	Earlier than REV A:	L211L	19C320618P6	Coil.	L229H	19C320617P17	Coil.	L243L	19C320617P42	Coil.
A115250Pl	Silicon, fast recovery, 225 mA, 50 PIV.	and L211M			1.2301.1.	19C320617Pl6	Coil.	1.243M	19C320617P43	Coil.
A115250P1	Silicon, fast recovery, 225 mA, 50 PIV.	L211H	19C320618P1	Coil.	L230L	19C320617P35	Coil.	L243H	19C320617P44	Coil,
		L2141L	19C320617P13	Coil.	L230M	19C320617P12	Coil.	1,2441.1,	19C320617P41	Coil.
	JACKS AND RECEPTACLES	12141	19C320617P32	Coil.	L230H	19C32O617P17	Coil.	L244L	19C320617P42	Coil.
A130924G1	Receptacle, coaxial: jack type; sim to Cinch 14H11613.	1.214 M	19C320617P18	Coil.	L231LL	19C320617P16	Coil.	L244M	19C320617P43	Coil.
		L214H	19C320617P14	Coil.	L231L	19C320617P35	Coil.	L244H	19C320617P44	Coil.
3219374G1	Connector: 9 contacts.	L215LL	19C320617P13	Coil.	L231M	19C320617P12	Coil.	L245LL	19A129360P9	Coil,
1134263P2	Contact, electrical: sim to Selectro 229-1071.	L215L	19C320617P33	Coil.	L231H	19C32O617P17	Coil.	L245L	19A129360P6	Coil.
		L215M	19C320617P34	Coil.	L23214	19C32O617P16	Coil.	L245M	19A129360P4	Coil.
33513₽4	Contact, electrical: sim to Bead Chain L93-3.	L215H	19C320617P18	Coil,	L232L	19C320617P35	Coil.	1.245H	19A129360P1	Coil.
		1.2161.1.	19C320617P13	Coil.	L232M	19C320617P12	Coil.	L246LL	19A129360P10	Coil.
1700061P1	Hermetic sealed: 180 to 341 ohms coil res, 8-16.3	L216L	19C320617P33	Coil.	L232H	19C32O617P17	Coil.	L246L	19A1293G0P7	Coil.
	VDC; sim to GE 3SAV1760A2 or Potter-Brumfield HCM6160.	L216M	19C32O617P34	Coil,	L233LL	19C32O618P2	Coil.	L246M	19A129360P3	Coil.
		L216H	19C320617P18	Coil,	L233L and	19C320618P6	Coil.	L24 6H	19A129360P2	Coil.
	INDUCTORS	L217LL	19C320617P15	Coil,	L233M			1.2471.L	19A129360P11	Coil,
2320617P1	Coil.	L217L	19C320617P5	Coil.	L233H	19C320618P1	Coil.	L247L	19A129360P8	Coil.
0320617P23	Coil,	L217M	19C320617P26	Coil.	L234LL	19C320618P2	Coil.	L247M	19A129360P5	Coil.
0320617P24	Coil.	L217H	19C320617P6	Coil.	L234L and	19C320618P6	Coil.	1.247н	19A129360P3	Coil,
0320617P2	Coil.	L218LL	19C320617P15	Coil.	L234M			L248LL	19A129360P9	Coil.
D320617P3	Coil.	1218L	19C320617P5	Co11.	1.234H	19C320618P1	Coil.	L248L	19A129360P6	Coil.
C320617P5	Coil.	L218M	19C320617P26	Coil.	L235LL	19C320618P2	Coil.	L248M	19A129360P4	Coil.
C320617P25	Coil.	1.218H	19C32O317P6	Coil.	L235L and	19C320618P6	Coil.	L248H	19A129360P1	Coil.
2320617P4	Coil.	L219LL	19C32O617P15	Coil.	L235M			L249LL	19C320617P41	Coil,
A700000P122	Coil, RF: 8.2 µb ±10%, 0.22 ohms DC res max.	£219£	19C320617P5	Coil.	L235H	19C320618Pl	Coil.	L249L	19C320617P42	Coil.
C320617P5	Coil.	T519M	19C320617P26	Coil.	لىن236ئىد	19C320618P2	Coil.	L249 M	19C320617P43	Coil.
C320617P26	Coil.	L219H	19C320617P6	Coil.	L236L and	19C320618P6	Coil.	L249H	19C320617P44	Coll.
C320617P27	Coil.	T550TT	19C32O617P15	Coil.	1,236M			L250LL	190320617P41	Coil.
2320617P6	Coil.	L220L	19C320617P5	Coil.	L236H	19C320618P1	Coil.	L250L	19C320617P42	Coil.
C320618P2	Coil.	L220M	19C320617P26	Coil.	L237LL	19C320617P37	Coil.	L250M	19C320617P43	Coil.
C320618P6	Coil.	1220Н	19C320617P6	Coil.	L237L	19C320617P38	Coil.	1.250H	190320617 P44	Coil, RF: 2.7 µh ±10%, 1.20 ohms DC res max.
		L221LL	19C320619P1	Coil,	L237M	19C320617P39	Coil.	L251 thru	19A700000P16	Согг, кг. 2.1 ра дом, 1100 опш 20 111
C320618P1	Coil.	L221L	19C320618P7	Coil,	L237H	19C320617P40	Coil.	1,254	194700000339	Coil, RF: 4.7 µh ±10%, 0.210 ohms DC res max.
C320617P7	Coil.	L221M	19C320619P5	Coil.	T738TT	19C320617P37	Coil.	1255	19A700000P19 19A700000P16	Coil, RF: 2.7 µh ±10%, 1.20 ohms DC res max.
C320617P28	Coil.	L221H	19C320619P6	Coil.	L238L	19C320617P38	Coil.	L256 and	15/100000110	
C320617P29	Coil.	L222LL	190320619P1	Coil.	L238M	19C320617P39	Coil.	L257	19A700000P17	Coil, RF: 3.3 µh ±10%, 0.140 ohms DC res max.
C320617P8	Coil.	L222L	19C320618P7	Coil.	1.238н	19C320617P40	Coil,	1,258	19A129346G1	Coil.
C320617P9	Coil.	L222M	19C320619P5	Coil.	L239LL	19C32O617P37	Coil,	L259 thru	19812534001	
C320617P30	Coil.	L222H	190320619P6	Coil,	L239L	19C320617P38	Coil,	L263		
C320617P31	Coil.	L223LL	19C320619Pl	Co11.	L239M	19C320617P39	Coil.	0911	19A115910P1	Silicon, NPN; sim to Type 2N3904.
C320617P10	Coil.	L222L	19C320618P7	Coil.	1.239н	19C320617P40	Co11,	Q211	19A115768P1	Silicon, PNP; sim to Type 2N3702.
C320619P1	Coil.	L222M	19C320619P5	Coil.	1,24.01.1	190320617237	Coil.	Q212 thru	TANTIBLOOM	
C320618P7	Coil.	L223H	19C320619P6	Co11.	L240L	19¢320617₽38	Coil,	Q214	19A115910P1	Silicon, NPN; sim to Type 2N3904.
C320619P5	Coil.	L2241L	19C320619P1	Coil.	L240M	19C320617P39	Coil.	Q215		Silicon, PNP; sim to Type 2N3251.
C320619P6	Coil, RF: 8.2 µh ±10%, 0.22 ohms DC res max.	L224L	19C320618P7	Co11.	L240H	19C320617P40	Coil.	Q216	19A115779P1	MARKON, the , was so sypt should
A700000P122	COII, Kr: 022 pm IIO%, 0.22 onns pe 100 max.	1.2 24 M	19C320619P5	Coil.	1.2411.1.	19C320617P41	Coil.			
		L224H	19C320619P6	Coil.	1.2411.	19C320617P42	Coil.			
					L241M	19C320617P43	Coil.			
			1		L241H	19C320617P44	Coil.			
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SYMB0L	GE PART NO.	DESCRIPTION	SYMBOL
L210LL	19C320617P11	Coil.	1,225
L210L	19C320617P4	Coil,	thru L228
and L210M			L229LL
L210H	19C320617P12	Coil.	12291
1211177	19C320618P2	Coil.	1229м
L211L and	19C320618P6	Coil.	L229H
L211M	10020021931	Coil,	L230LL
L211H L214LL	19C320618P1 19C320617P13	Coil.	1230L 1230M
L214L	19C320617P32	Coil.	1230н
L214M	19C32O617P18	Coil.	L231LL
1.214H	19C320617P14	Coil.	L231L
L215LL	19C320617P13	Coil.	L231M
L215L	19C32O617P33	Coil.	L231H
L215M	19C320617P34	Coil.	123214
L215H	19C32O617P18	Coil,	L232L
121614	19C320617P13	Coil,	1232M
L216L	19C320617P33	Coil.	L232H
L216M	19C320617P34	Coil,	L233LL
L216H	19C320617P18	Coil,	L233L and
L217LL	19C320617P15	Coil.	1.233M
L217L	19C320617P5	Coil.	1233Н
L217M	19C320617P26 19C320617P6	Coil.	1.2341.1.
L217H L218LL	19C320617P15	Coil.	1,234 L and 1,234 M
L218L	19C320617P5	Coll.	L234H
L218M	19C320617P26	Coil.	L235LL
L218H	19C320617P6	Coil,	L235L and
1,2191.L	19C320617P15	Coil.	L235M
L219L	19C320617P5	Coil.	1.235H
L219M	19C320617P26	Coil.	L236LL L236L
L219H L220LL	19C320617P6 19C320617P15	Coil.	and L236M
L220L	19C320617P5	Coil.	1,236H
L220M	19C320617P26	Coil,	L2371.1.
L220H	190320617P6	Coil.	L237L
1.2211.1.	19C32O619P1	Coil.	L237M
L221L	19C320618P7	Coil,	L237H
1.22111	19C320619P5	Coil.	L23814.
L221H	19032061926	Coil,	L238L
L222LL	19C32O619Pl	Coil.	L238M
L222L	19C320618P7	Coil.	L238H
1.222M	19C32O619P5	Coil.	1.2391.1
L222H	19C320619P6	Coil.	L239L
L223LL	19C320619Pl	Coil.	L239M
L222L	19C320618P7	Coil.	L239H
L222M	19C320619P5	Coil.	1.24 01.1.
L223H	19C320619P6	Coil.	L240L
1,2241,1.	19C320619Pl	Coll.	1.240M
L224L	19032061897	Coil.	L240H
L224M	19C32O619P5	Coil.	1.2411.1
L224H	19C32O619P6		1.241L 1.241M
			1.24 1 H
			1,2418
i			1 1

GE PART NO.

19A700000P122

19C320617P16

19C320617P35

19C320617P12

190320617217

19C320617P16

19C320617P35

19C320617P12

19C320617P17

19C320617P16

19C320617P35

19C320617P12

19C320617P17

19C320617P16

19C320617P35 19C320617P12

19C320617P17

19C320618P2

19C320618P6

19C320618P1

19C320618P2

19C320618P6

19C320618P1

19C320618P2

19C320618P6

19C320618Pl

19C320618P2

19C320618P6

19C320618P1

19C320617P37

19C320617P38

19C320617P39

19C320617P40

19C320617P37

19C320617P38

19C320617P39

19C320617P40

19C320617P37

19C32O617P38

19C320617P39

19C320617P40

19C320617P37

19C320617P38

19C320617P39

19C320617P40

19C320617P41

19C320617P42 19C320617P43

19C320617P44

Coil, RF: 8

Coil.

Coil.

Coil.

Coil.

Coil.

Co11.

Coll.

Coil.

Coll.

Coil.

DF-3155

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION		SYMBOL	GE PART NO.	DESCRIPTION
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R201	19A700106P77	Composition 2 GV object 45% 1/4 m	R222L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.		R235M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.
R201	3R152P511J	Composition: 3.9K ohms ±5%, 1/4 w. Composition: 510 ohms ±5%, 1/4 w.	R222M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.		R235H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.
R203LL	19A700113P17	Composition: 12 ohms ±5%, 1/2 w.	н222Н	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.		R236 thru R243	19A700113P29	Composition: 39 ohms ±5%, 1/2 w.
R203L	19A700113P15	Composition: 10 ohms ±5%, 1/2 w.	R223LL R223L	19A700113P11 19A700113P5	Composition: 6.8 ohms ±5%, 1/2 w. Composition: 3.9 ohms ±5%, 1/2 w.		R243 R244	19A700111P39	Composition: 100 ohms ±5%, 2 w,
н203м	19A700113P13	Composition: 8.2 ohms ±5%, 1/2 w.	R223E R223M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.		thru R246	154/001117.55	Composition: 100 offins 15%, 2 %,
R203H	19A700113P7	Composition: 4.7 ohms ±5%, 1/2 w.	R223H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	1	R249	19C320212P2	Shunt resistor.
R204LL	19A700113P17	Composition: 12 ohms ±5%, 1/2 w.	R22414L	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	11	R250	19C320212P1	Shunt resistor.
R204L	19A700113P15	Composition: 10 ohms ±5%, 1/2 w.	R224L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.		and #251		
R204M	19A700113P13	Composition: 8.2 ohms ±5%, 1/2 w.	R224M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.		R252	19A700106P91	Composition: 15K ohms ±5%, 1/4 w.
R204H	19A700113P7	Composition: 4.7 ohms ±5%, 1/2 w.	R224H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.		R253	19A700106P83	Composition: 6.8K ohms ±5%, 1/4 w.
R205	19A700113P29	Composition: 39 ohms ±5%, 1/2 w.	R225LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.		R254	19A700106P39	Composition: 100 ohms ±5%, 1/4 w.
and R206			R225L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.		R255	19A116278P253	Metal film: 3480 ohms ±%, 1/2 w.
R207LL	19A700113P59	Composition: 680 ohms ±5%, 1/2 w.	R225M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	11	R256	19A116278P201	Metal film: 1K ohms ±2%, 1/2 w.
R207L	19A700113P59	Composition: 680 ohms ±5%, 1/2 w.	к225н	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.		R257	19A116278P261	Metal film: 4220 ohms ±2%, 1/2 w.
R207M	19A700113P59	Composition: 680 ohms ±5%, 1/2 w.	R226LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.		R258	19A116278P269	Metal film: 5110 ohms ±2%, 1/2 w.
R207H	3R78P911J	Composition: 910 ohms ±5%, 1 w.	R226L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.		£259	19A116278P261	Metal film: 4.22K ohms ±2%, 1/2 w.
R208££	19A700112P59	Composition: 680 ohms ±5%, 1 w.	R226M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	****	R261	19Al16559P102	Variable, cermet: 5K ohms ±20%, .5 w; sim to CTS Series 360.
R2081	19A700112P59	Composition: 680 ohms ±5%, 1 w.	R226H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.		R262	19A700106P39	Composition: 100 ohms ±5%, 1/4 w.
R208M	19A700112P59	Composition: 680 ohms ±5%, 1 w.	R227LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.		H263	19A700106P83	Composition: 6.8K ohms ±5%, 1/4 w.
R208H	3R78P911J	Composition: 910 ohms ±5%, 1 w.	R227L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.		R264	19A700113P41	Composition: 120 ohms ±5%, 1/2 w.
R20914	19A700112P13	Composition: 8.2 ohms ±5%, 1 w.	R227M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.		R235	19A700113P55	Composition: 470 ohms ±5%, 1/2 w.
R209L	19A700112P13	Composition: 8.2 ohms ±5%, 1 w.	R227H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.		R266	19A700106P63	Composition: 1K ohms ±5%, 1/4 w.
R209M	19A700112P13	Composition: 8.2 ohms ±5%, 1 w.	R228LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.		R267	19A700106P69	Composition: 1.8K ohms ±5%, 1/4 w.
R209H	19A700112P9	Composition: 5.6 ohms ±5%, 1 w.	R228L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.		R268	19A700106P15	Composition: 10 ohms ±5%, 1/4 w.
							11200	100100110	
R2101L	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R228M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	Ιİ	R269	19A700113P15	Composition: 10 ohms ±5%, 1/2 w.
R210L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R228H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.		R270	3R152P241J	Composition: 240 ohms ±5%, 1/4 w.
R210M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R229LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.		R271	19A700106P75	Composition: 3.3K ohms ±5%, 1/4 w.
R210H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R229L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.		R272	19A700113P15	Composition: 10 ohms ±5%, 1/2 w.
R211LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R229M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	11	R273 thru	3R78P100K	Composition: 10 ohms ±10%, 1 w.
R211L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	к229н	7147161P22	Composition: 1.2 ohus ±5%, 1/2 w.		R277		
R211M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R230LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.				VOLTAGE REGULATORS
R211H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w. Composition: 6.8 ohms ±5%, 1/2 w.	R230L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.		VR201	4036887P1	Zener: 500 mW, 2.3 v. nominal.
R2121.L	19A700113P11 19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R230M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.		VR202	4036887P5	Zener: 500 mW, 5.4 v. nominal.
R212L R212M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R230H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.				
R212M R212H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R231144	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.		n201	19A129571P1	Strap.
R213LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R231L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.		w202	198219998 P 2	Jumper.
R213L	19A700113P1	Composition: 3.9 ohms ±5%, 1/2 w.	R231M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.		w203	198219998P1	Jumper,
R213L R213M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R231H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.		h204	19C320624P1	Strip, connector.
R213H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R232LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w. Composition: 3.9 ohms ±5%, 1/2 w.		w205		(Part of printed wiring board 19B417923P1).
R213H R214	19A700113P29	Composition: 39 ohms ±5%, 1/2 w.	R232L	19A700113P5	Composition: 3.9 onms 15%, 1/2 w. Composition: 2.0 ohms ±5%, 1/2 w.		thru #209		
and R215			R232M	7147161P27 7147161P22	Composition: 2.0 ohms ±5%, 1/2 w.				
R216	19A700112P39	Composition: 100 ohms ±5%, 1 w.	R232H	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.				HEAT SINK ASSEMBLY 19B219688G6 M MODEL AND INTERMITTANT DUTY STATION
thru R218			R233LL R233L	19A700113P1	Composition: 3.9 ohms ±5%, 1/2 w.				19B219688G18 E ADDEL
R220LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R233L R233M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.				
R220L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R233H	7147161P27 7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.		C297	19A116708P1	Ceramic, feed-thru: 0.01 µf +100% -0%, 500 VDCW;
R220M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R234LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.		and C298		sim to Erie Style 327.
R220H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R234L	19A700113P11	Composition: 3.9 ohms ±5%, 1/2 w.	1 1	C299	19A115680P10	Electrolytic: 200 µf +150% -10%, 18 YDC%; sim
R221LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R234M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.				to Mallory Type TTX.
R221L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R234H	7147161P27 7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.				DIODES AND RECTIFIERS
R221M	7147161P27	Composition; 2.0 ohms ±5%, 1/2 w.	R235LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.		CR295	19A116783P1	Silicon.
R221H	Composition; l.	2 ohms ±5%, 1/2 w.	R235L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.				
R222LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.							
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SYMBOL	GE PART NO.	DESCRIPTION CONTROL OF THE PROPERTY OF THE PRO
		MISCELLANEOUS
	19A129361P1	Shield. (Located between L246 & L247, L L248).
	19A129361P2	Shield. (Located between L245 & L246),
	19D416275P2	Filter casting.
	19A134016P1	Insulator, bushing. (Used with Q217).
	19All6023Pl	Insulator, plate. (Used with Q217).
	19D416712P6	Insulator, (Located under Power Amplifi
	19A129661P1	Insulator. (Located at L298).
	198201074P312	Tap screw, Phillips POZIDRIV®: No. 6-32 (Secures Filter Casting).
	5492178P2	washer, spring tension: sim to wallace 375-20. (Used with Q204-Q209).
	N207P15C6	Hexnut: No. 8-32. (Used with Q204).
	19A129434P1	Washer. (Used with C297, C298).
	N207P16C6	Nut, hex: No. 10-32. (Used with Q205-Q
	1.	

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a Letter," which is stamped after the model number of the unit. The revision stamped on the unit previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A - Power Amplifier Board 19D417927G1-4

To improve operation. Changed CR201.

REV. B - Power Amplifier Board 19D417927G1

To improve stopband attenuation (25-30 MHz range) Changed C4201LL and C4206LL.

REV. B - Power Amplifier Board 19D417927G2-4

REV. C - Power Amplifier Board 19D417927G1

To improve operation of power control circuit, Added C42;

REV. C - Power Amplifier Board 19D417927G2

To improve low pass filter response. Changed C4205L.

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'ION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
rors ~	R222L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R235M	7147161927	Composition: 2.0 ohms ±5%, 1/2 w.
5%, 1/4 w.	R222M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	н235н	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.
6, 1/4 w.	R222H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R236	19A700113P29	Composition: 39 ohms ±5%, 1/2 w.
1/2 w.	R223LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	thru R243		-
, 1/2 w.	R223L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R244	19A700111P39	Composition: 100 ohms ±5%, 2 w.
i, 1/2 w.	R223M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	thru 8246		
5, 1/2 w.	R223H	7147161P22	Composition: 1,2 ohms ±5%, 1/2 w.	R249	19C320212P2	Shunt resistor.
, 1/2 w.	R224LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R250	190320212P1	Shunt resistor.
1/2 w.	R224L	19470011325	Composition: 3.9 ohms ±5%, 1/2 w.	and R251		
, 1/2 w.	R224M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R252	19A700106P91	Composition: 15K ohms ±5%, 1/4 w.
, 1/2 w.	R224H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R253	19A700106P83	Composition: 6.8K ohms ±5%, 1/4 w.
1/2 w.	R225LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R254	19A700106P39	Composition: 100 ohms ±5%, 1/4 w.
	R225L	19A700113P1	Composition: 3.9 ohms ±5%, 1/2 w.	R255	19A116278P253	Metal film: 3480 ohms ±a, 1/2 w.
, 1/2 w.	R225L	7147161927	Composition: 2.0 ohms ±5%, 1/2 w.	R256	19A116278P201	Metal film: 1K ohms ±2%, 1/2 w.
, 1/2 w.		7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R257	19A116278P261	Metal film: 4220 ohms ±2%, 1/2 w.
, 1/2 w.	R225H		· ·	R258	19A116278P269	Metal film: 5110 ohms ±2%, 1/2 w.
,, 1 w.	R226LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w. Composition: 3.9 ohms ±5%, 1/2 w.	R259	19A116278P261	Metal film: 4.22K ohms ±2%, 1/2 w.
l l	R226L	19A700113P5	•			Variable, cermet: 5K ohms ±20%, .5 w; sim to
,, 1 w.	R226M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R261	19A116559P102	CTS Series 360.
,, 1 w.	R226H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R262	19A700106P39	Composition: 100 ohms ±5%, 1/4 w.
1 w.	R227LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R263	19A700106P83	Composition: 6.8K ohms ±5%, 1/4 w.
1 W.	R227L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R264	19A700113P41	Composition: 120 ohms ±5%, 1/2 w.
,, 1 w.	R227M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R2 85	19A700113P55	Composition: 470 ohms ±5%, 1/2 w.
,, 1 w.	R227H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R266	19A700106P63	Composition: 1K ohms ±5%, 1/4 w.
, 1 w.	R228LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R267	19A700106P69	Composition: 1.8K ohms ±5%, 1/4 w.
, 1 W.	R228L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R268	19A700106P15	Composition: 10 ohms ±5%, 1/4 w.
, 1/2 w.	R228M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R269	19A700113P15	Composition: 10 ohms ±5%, 1/2 w.
, 1/2 w.	R228H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	R270	3R152P241J	Composition: 240 ohms ±5%, 1/4 w.
, 1/2 w.	R22914	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	R271	19A700106P75	Composition: 3.3K ohms ±5%, 1/4 w.
., 1/2 w.	R229L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	R272	19A700113P15	Composition: 10 ohms ±5%, 1/2 w.
,, 1/2 w.	R229M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	R273	3R78P100K	Composition: 10 ohms ±10%, 1 w.
ı, 1/2 w.	R229H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	thru R277		
, 1/2 w.	R230LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.			VOLTAGE REGULATORS
, 1/2 w.	R230L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	VR201	4036887Pl	Zener: 500 mW, 2.3 v. nominal.
, 1/2 w.	R230M	7147161P27	Composition; 2.0 ohms ±5%, 1/2 w.	VR202	4036887P5	Zener: 500 mm, 5.4 v. nominal.
, 1/2 w.	R230H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.			
, 1/2 w.	R231LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.			
, 1/2 w.	R231L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	W201	19A129571P1	Strap.
, 1/2 w.	R231M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	w202	19B219998P2	Jumper.
,, 1/2 w.	R231H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.	n203	19B219998P1	Jumper.
, 1/2 w.	R231H R232LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	w204	19C320624P1	Strip, connector.
, 1/2 w.		19A700113P11	Composition: 3.9 ohms ±5%, 1/2 w.	w205 thru	ļ	(Part of printed wiring board 19D417923P1).
, 1/2 w.	R232L	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.	w209		
	R232M	1	Composition: 1.2 ohms ±5%, 1/2 w.			
, 1 w.	R232H	7147161P22	Composition: 6.8 ohms ±5%, 1/2 w.			HEAT SINK ASSEMBLY 19B21968BG6 M MODEL AND INTERMITTANT DUTY STATION
-	R233LL	19A700113P11	Composition: 3.9 ohms ±5%, 1/2 w.			19B219688G18 E MODEL
5, 1/2 w.	R233L	19A700113P5	Composition: 2.0 ohms ±5%, 1/2 w.			
i, 1/2 w.	R233M	7147161P27	Composition: 1.2 ohms ±5%, 1/2 w.	0207	19A116708P1	Ceramic, feed-thru: 0.01 µf +100% -0%, 500 VDCW;
5, 1/2 w.	R233H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w. Composition: 6.8 ohms ±5%, 1/2 w.	C297 and	12411010051	sim to Erie Style 327.
5, 1/2 w.	R234LL	19A700113P11		C298	104115200010	Electrolytic: 200 µf +150% -10%, 18 VDCW; sim
6, 1/2 w.	R234L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.	C299	19A115680P10	to Mallory Type TTX.
6, 1/2 w.	R234M	7147161P27	Composition: 2.0 ohms ±5%, 1/2 w.			DIODES AND RECTIFIERS
6, 1/2 w.	R234H	7147161P22	Composition: 1.2 ohms ±5%, 1/2 w.			
υ, 1/2 π,	R235LL	19A700113P11	Composition: 6.8 ohms ±5%, 1/2 w.	CR295	19A116783P1	Silicon.
4 1/2 w	R235L	19A700113P5	Composition: 3.9 ohms ±5%, 1/2 w.			
6, 1/2 w.						
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SYMBOL	GE PART NO.	DESCRIPTION
		MISCELLANEOUS
	19A129361P1	Shield. (Located between L246 & L247, L247 & L248).
	19A129351P2	Shield. (Located between L245 & L246).
	19D416275P2	Filter casting.
	19A134016P1	Insulator, bushing. (Used with Q217).
	19A116023P1	Insulator, plate. (Used with Q217).
	19D416712P6	Insulator. (Located under Power Amplifier Board).
	19A129661P1	Insulator. (Located at L298).
	198201074P312	Tap screw, Phillips POZIDRIY $^{\odot}$: No. 6-32 x 3/4. (Secures Filter Casting).
	5492178P2	Washer, spring tension: sim to mallace Harnes 375-20. (Used with Q204-Q209).
	N207P15C6	Hexnut: No. 8-32. (Used with Q204).
	19A129434P1	Washer. (Used with C297, C298).
	N207P16C6	Nut, hex: No. 10-32. (Used with Q205-Q209).

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter," which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A - Power Amplifier Board 19D417927G1-4

To improve operation. Changed CR201.

REV. B - Power Amplifier Board 19D417927G1

To improve stopband attenuation (25-30 MHz range) Changed C4201LL and C4206LL.

REV. B - Power Amplifier Board 19D417927G2-4

REV. C - Power Amplifier Board 19D417927G1

To improve operation of power control circuit. Added C4230,

REV. C - Power Amplifier Board 19D417927G2

To improve low pass filter response. Changed C4205L.